

NEXT-100 Mechanical Overview

Derek Shuman

Lawrence Berkeley National Laboratory

December 2, 2012

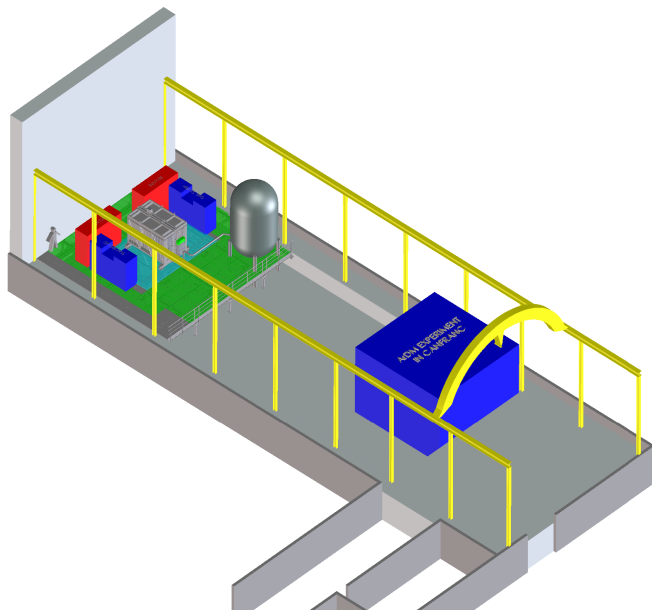
Mechanical

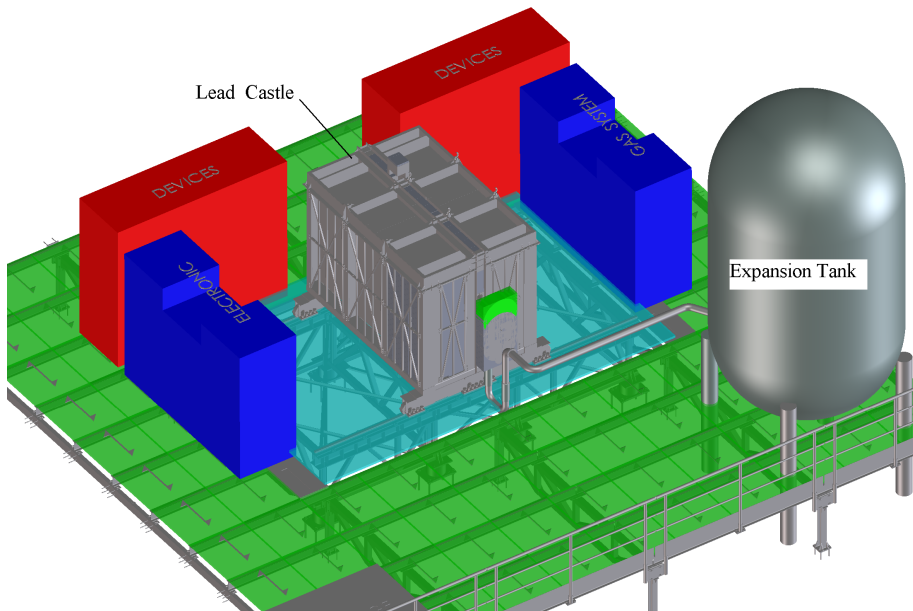
- Derek Shuman LBNL (lead, past)
- Sara Carcel, IFIC (lead, present)
- Alberto Martinez, IFIC

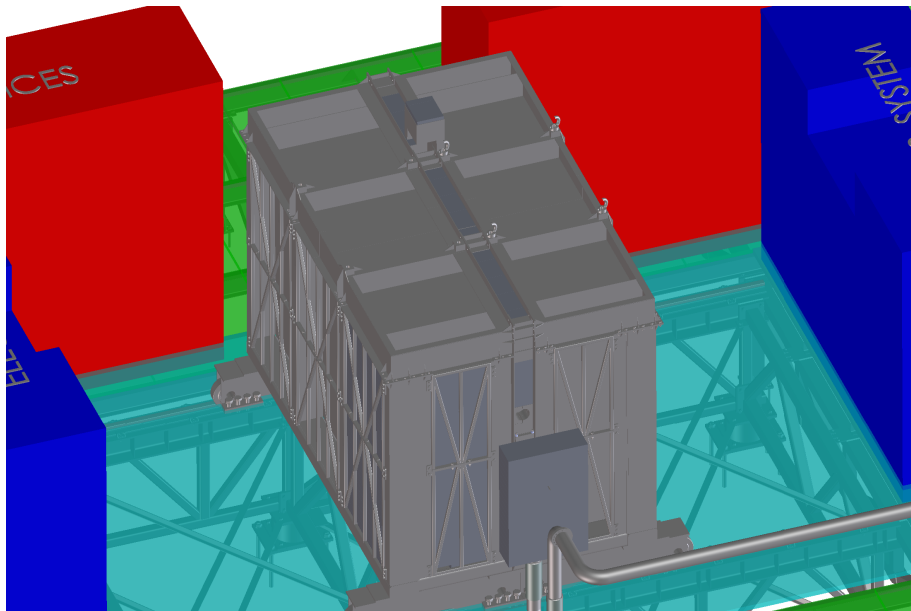
Civil

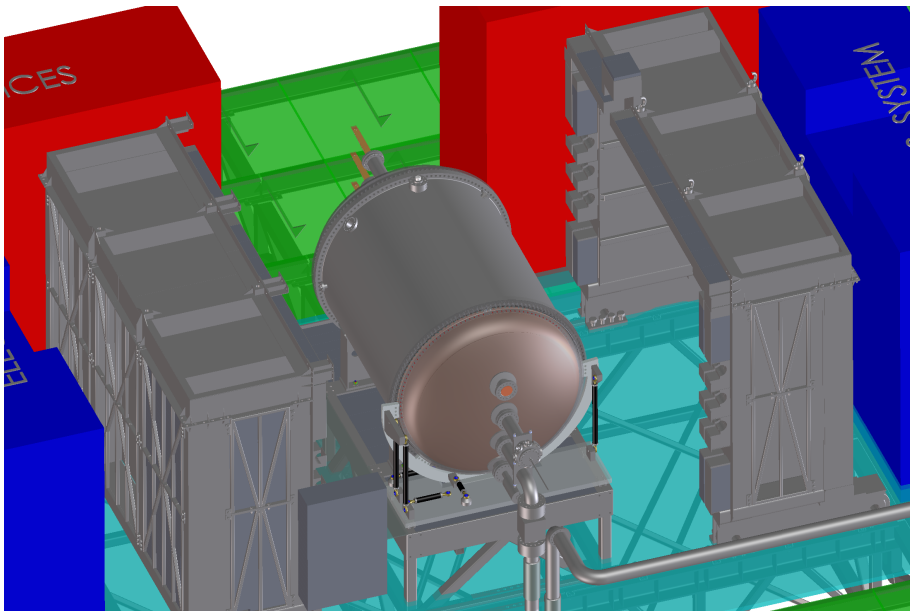
- Jose Luis Perez Aparicio, University Polytechnica de Valencia (lead)
- Jordi Torrent Collell, Escola Politecnica superior, University de Girona
- Roberto Palma, UPV



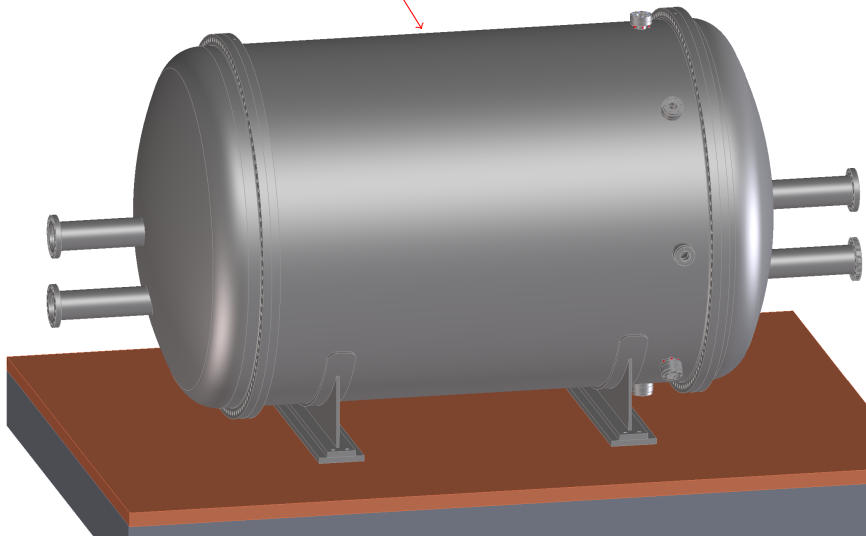




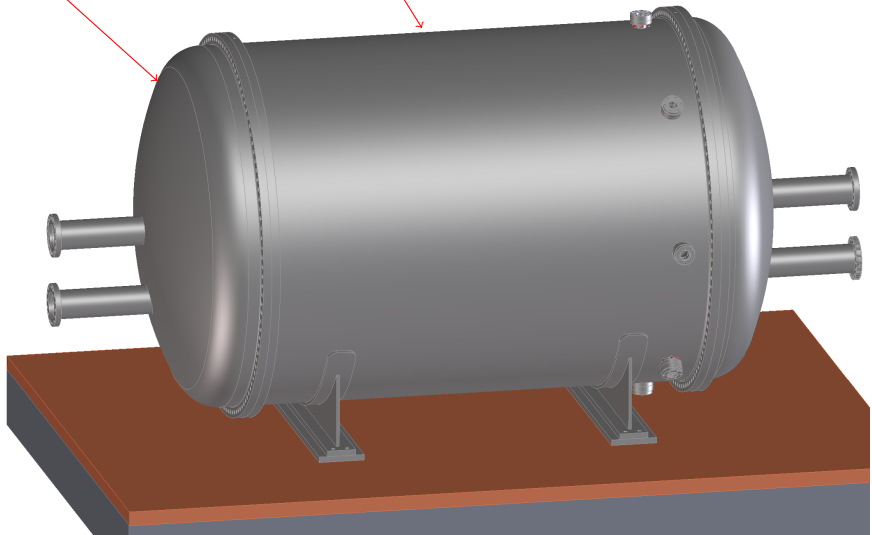




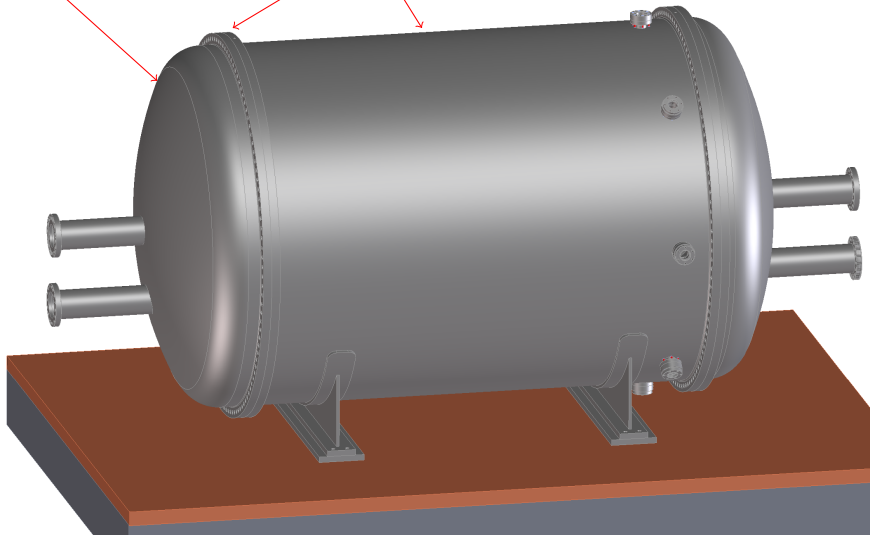
Main Cylindrical Vessel

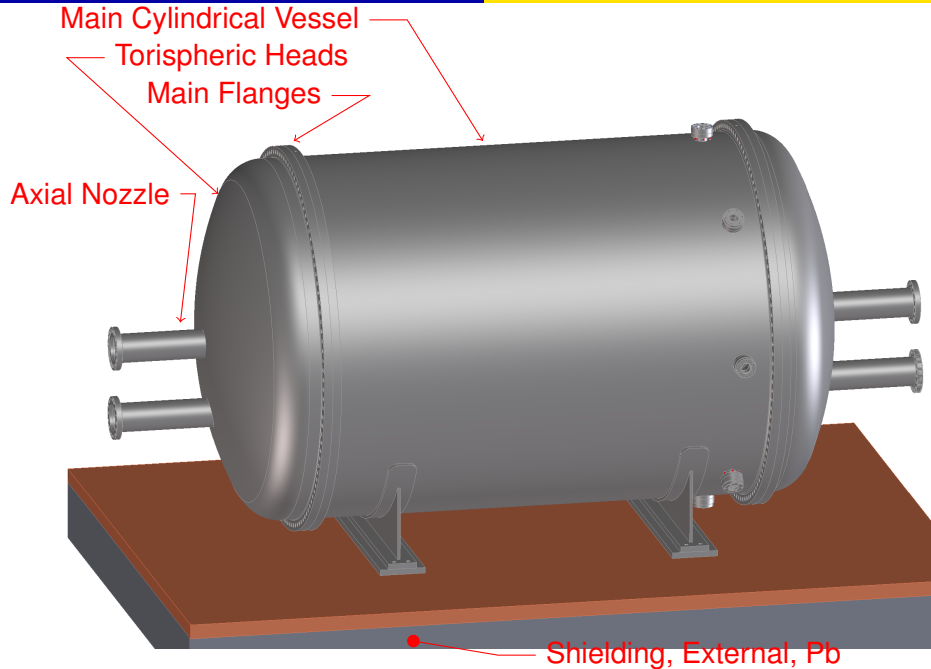


Main Cylindrical Vessel
Torispheric Heads



Main Cylindrical Vessel
Torispheric Heads
Main Flanges





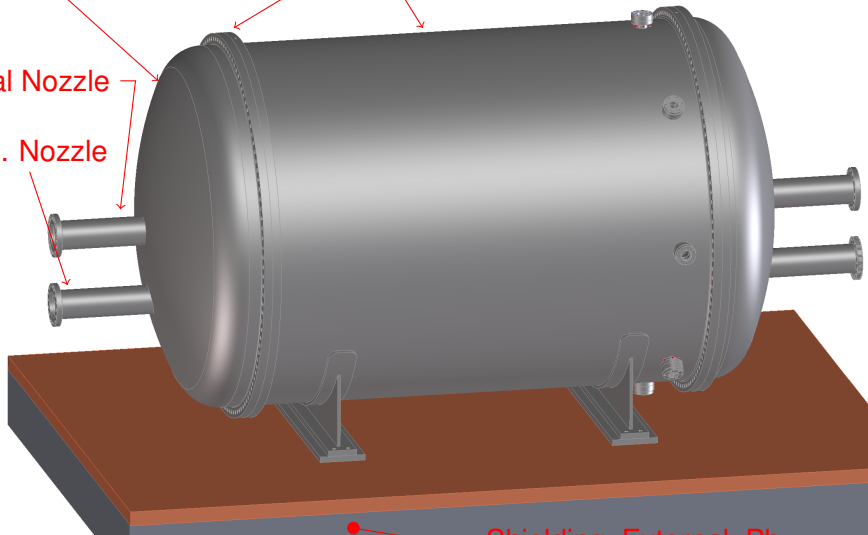
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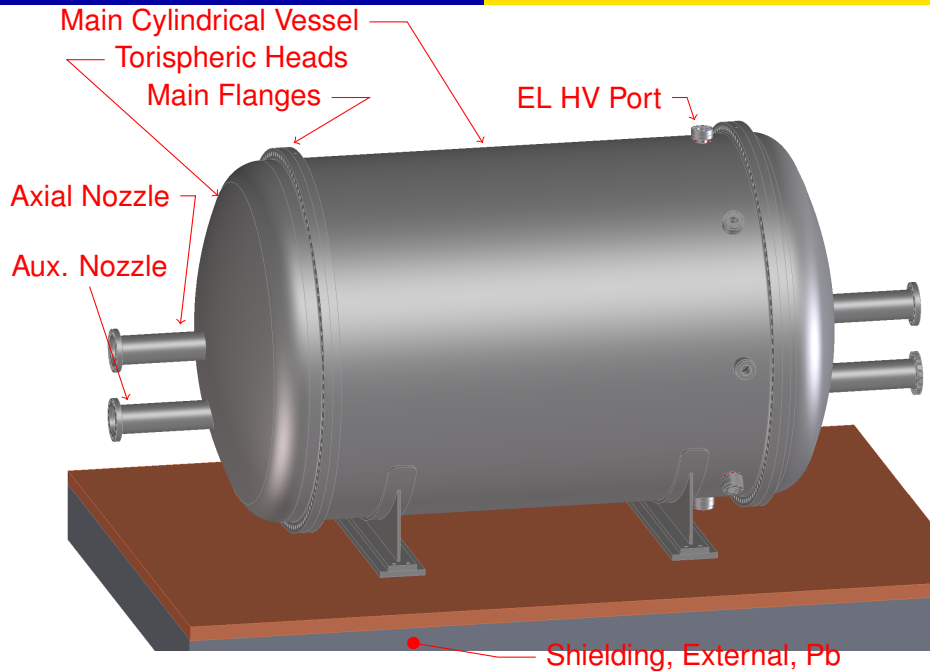
Main Flanges

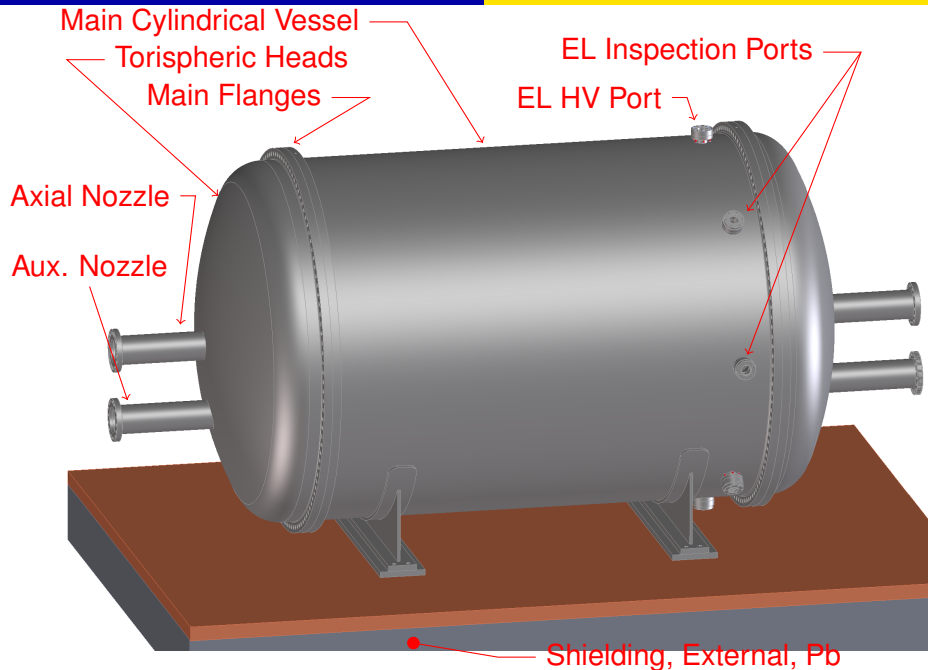
Axial Nozzle

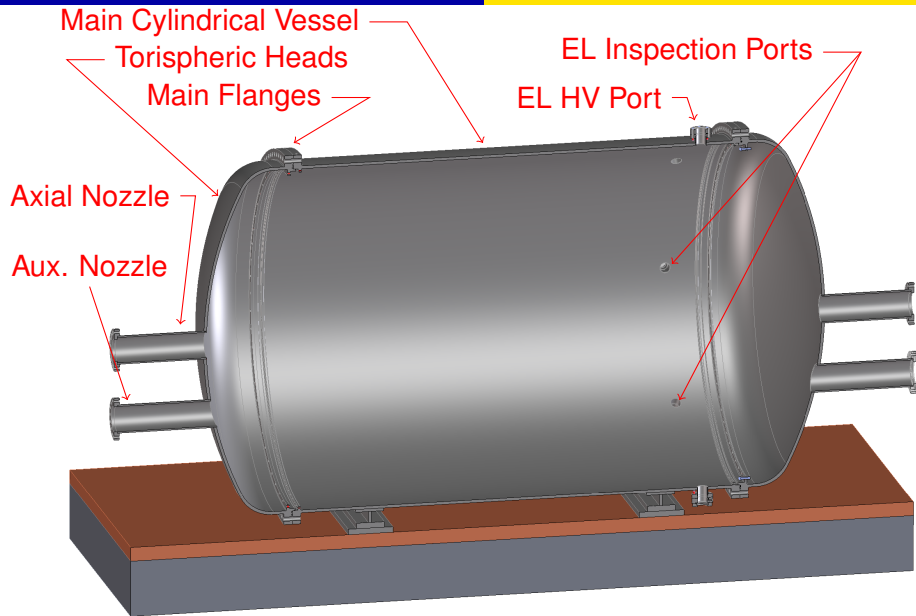
Aux. Nozzle

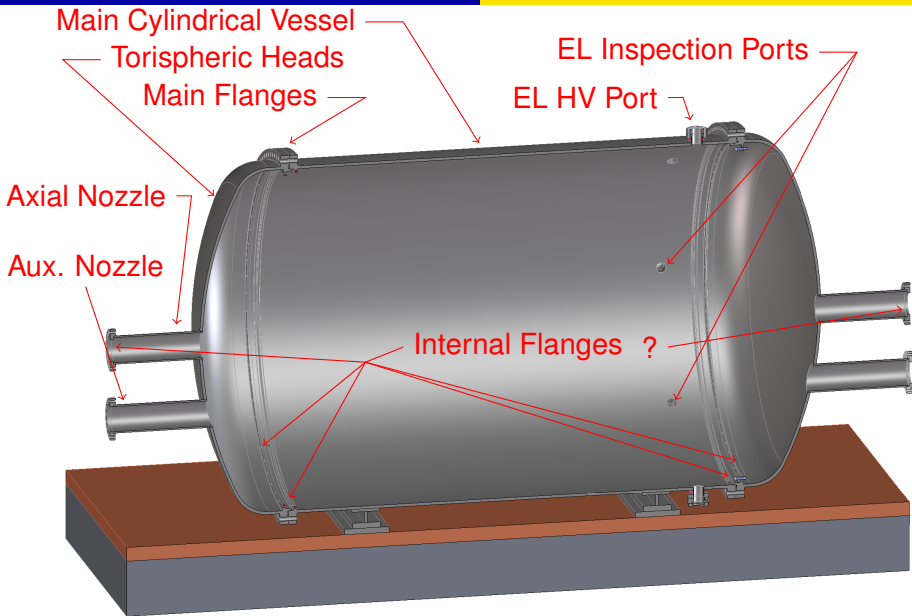


Shielding, External, Pb



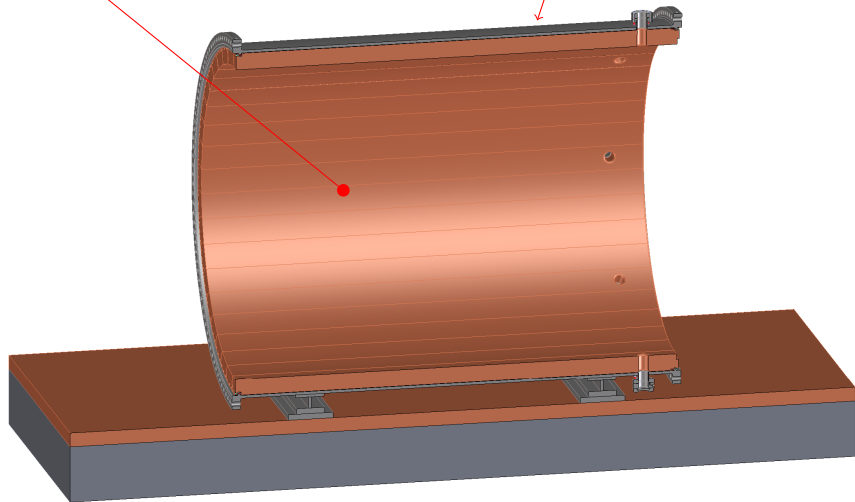






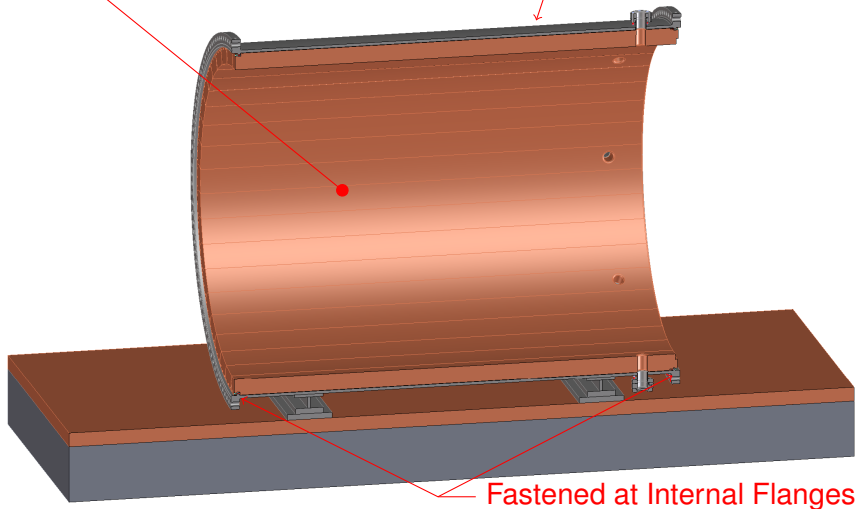
Main Cylindrical Vessel

Cu Shield Bars, 40x 70 kg. ea.

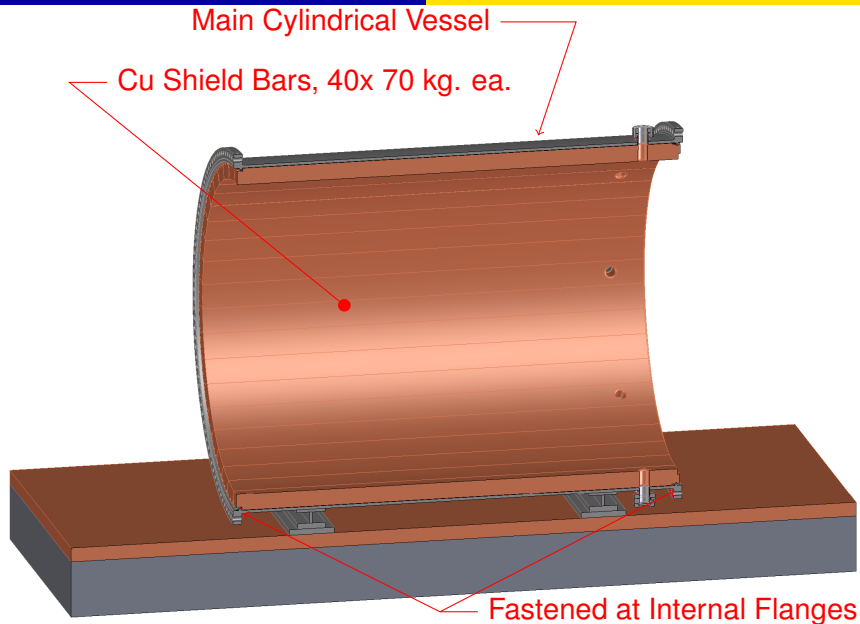


Main Cylindrical Vessel

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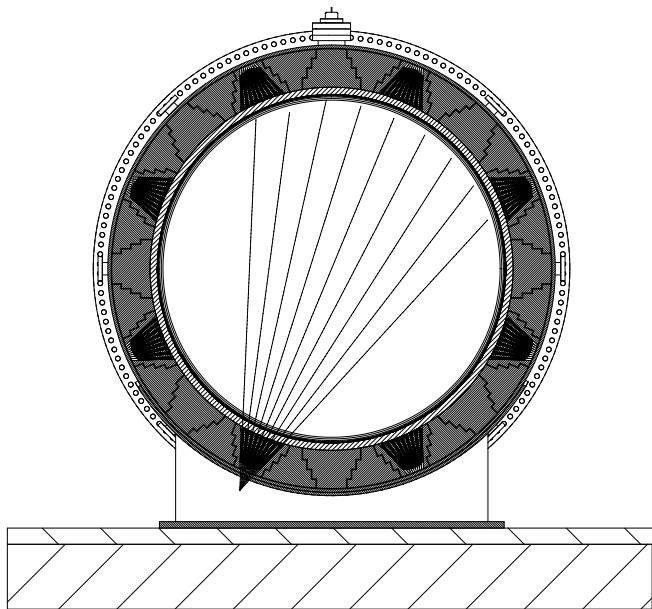


Fastened at Internal Flanges



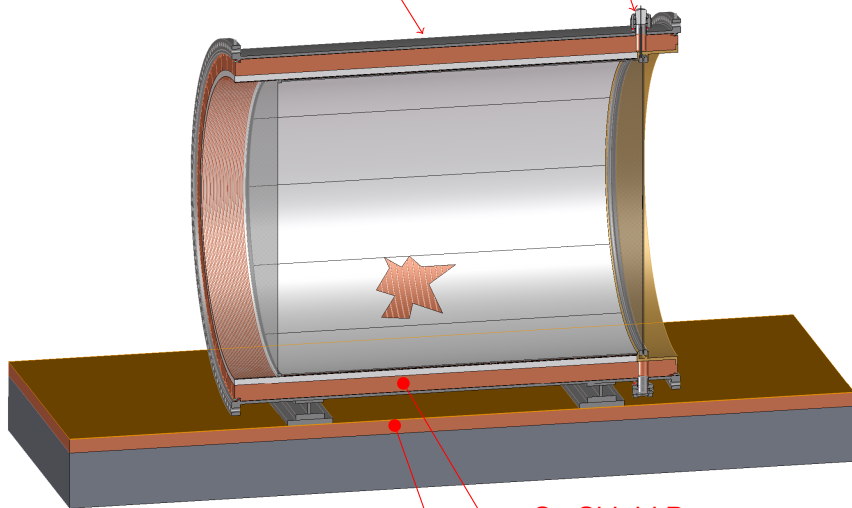
Supported on Ends, low stress, no vessel contact

End view of ICS bars showing possible external source collimators



Main Cylindrical Vessel

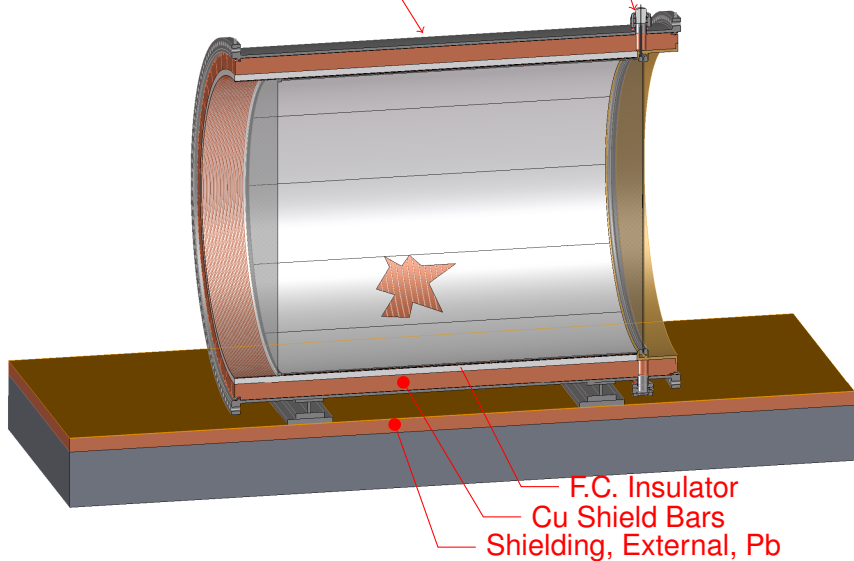
EL HV F.T.



Cu Shield Bars
Shielding, External, Pb

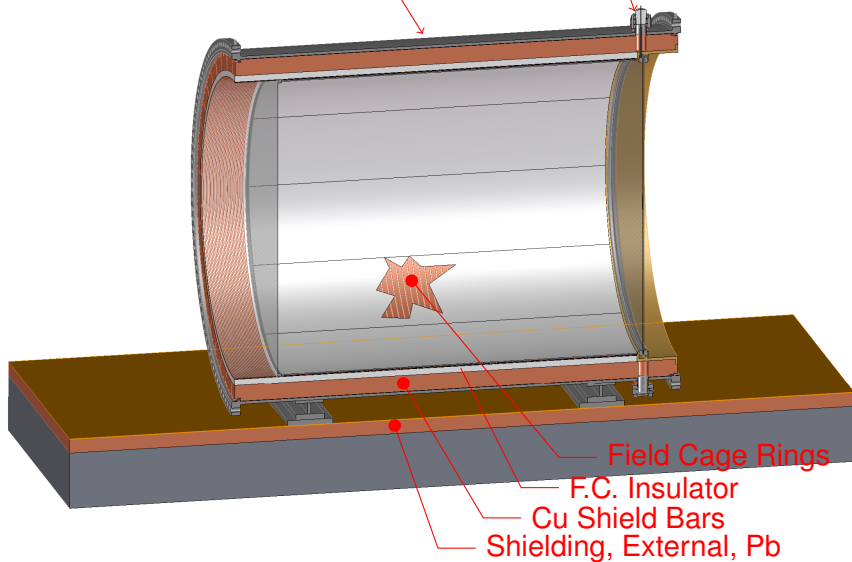
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Main Cylindrical Vessel

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Field Cage Rings

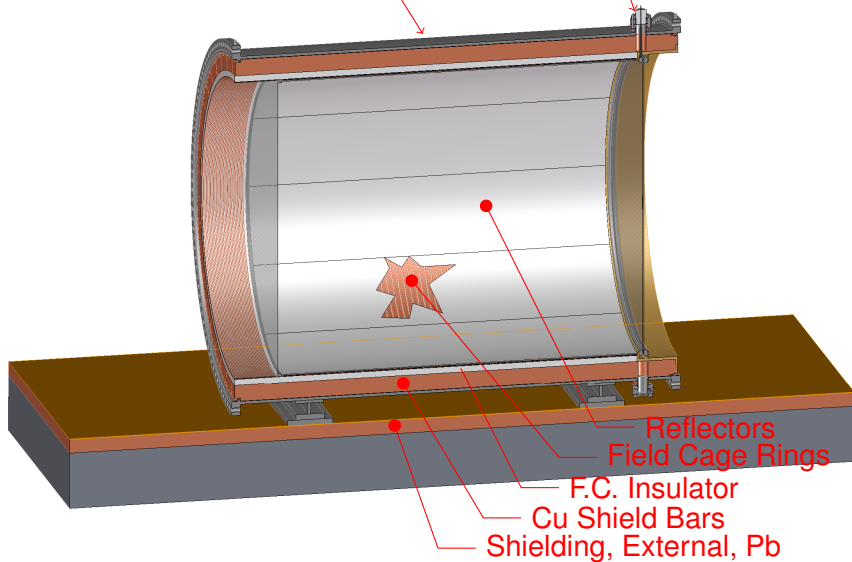
F.C. Insulator

Cu Shield Bars

Shielding, External, Pb

Main Cylindrical Vessel

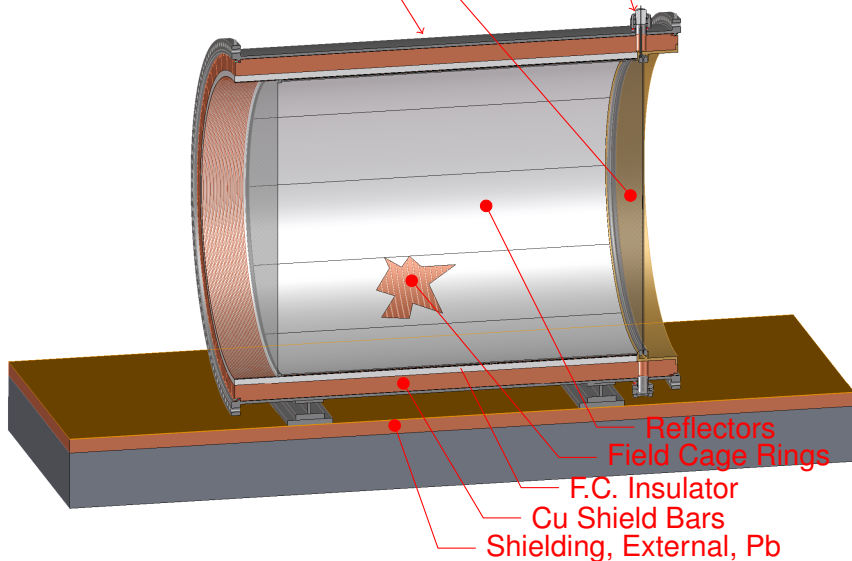
EL HV F.T.



Main Cylindrical Vessel

EL mesh planes

EL HV F.T.

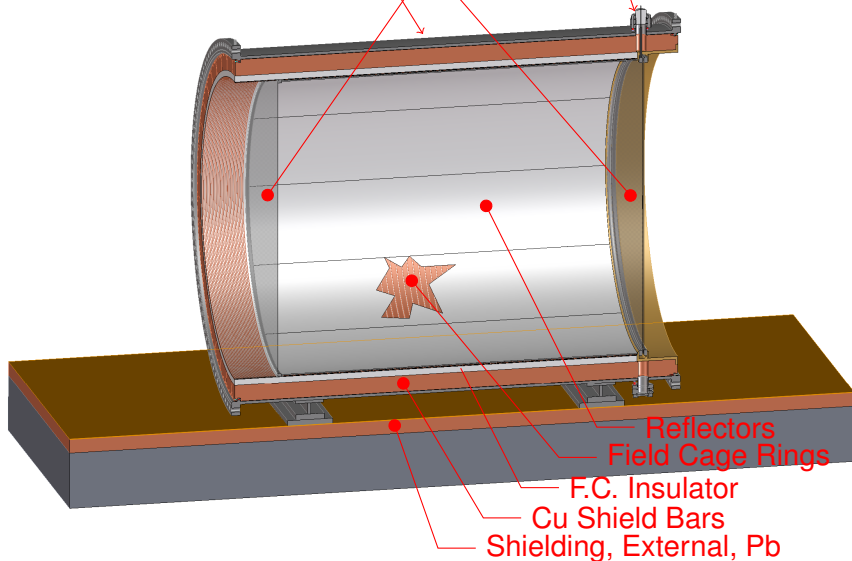


Main Cylindrical Vessel

EL mesh planes

Cathode

EL HV F.T.

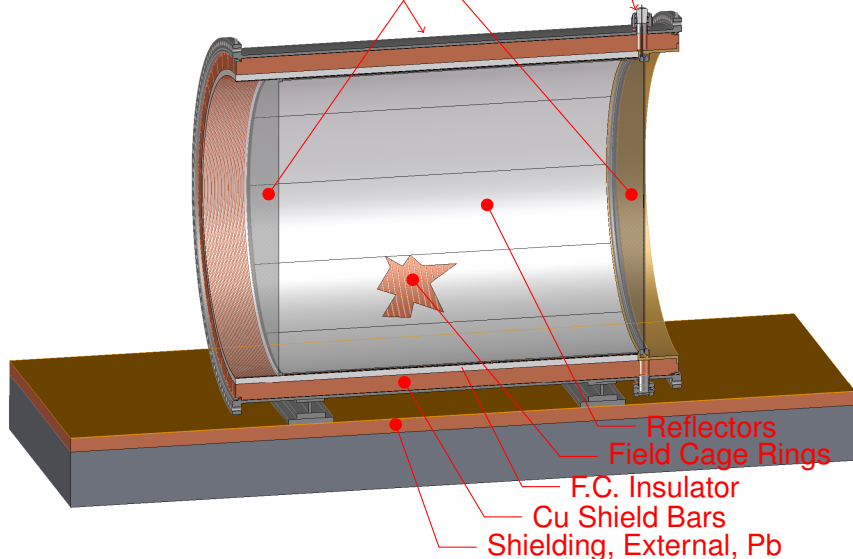


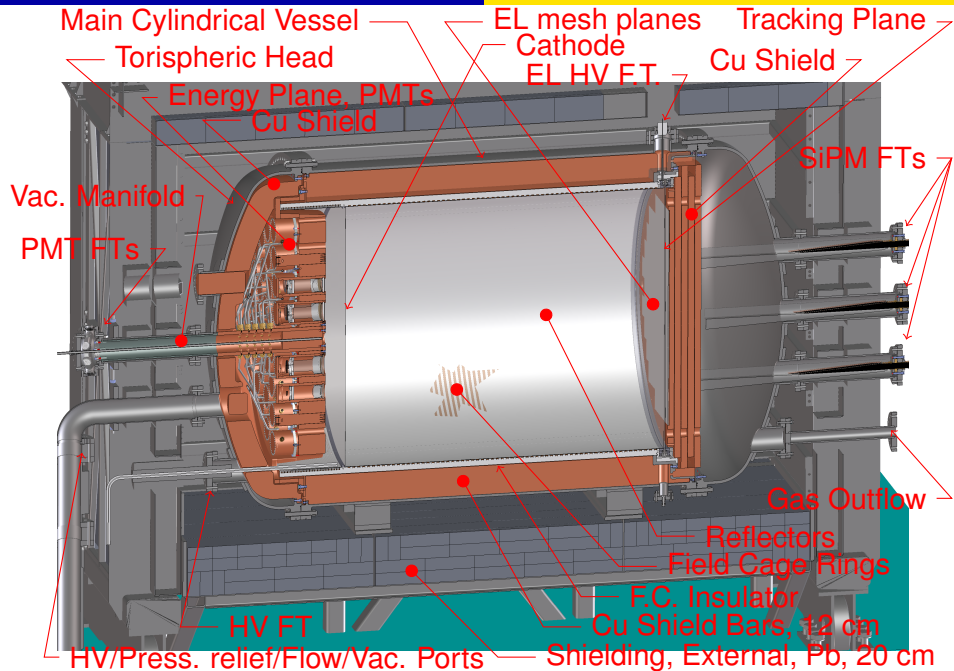
Main Cylindrical Vessel

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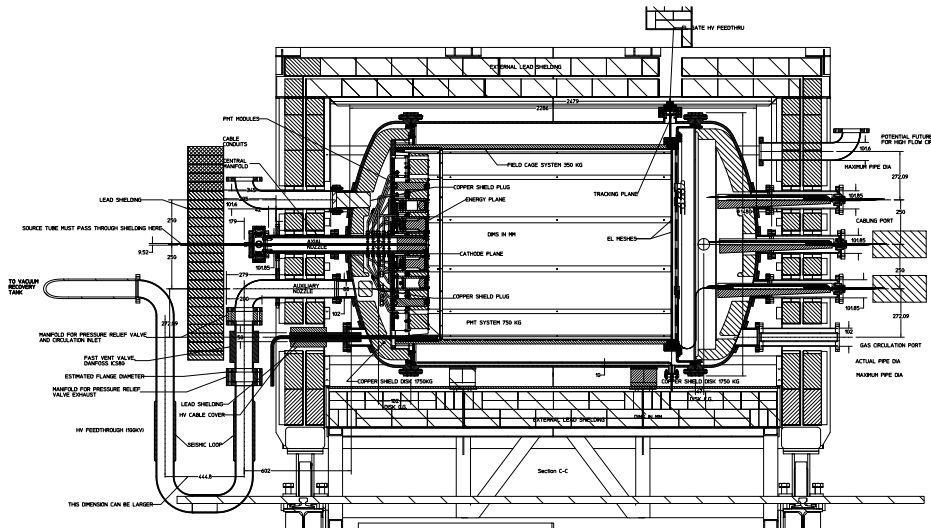
Cathode

EL HV F.T.

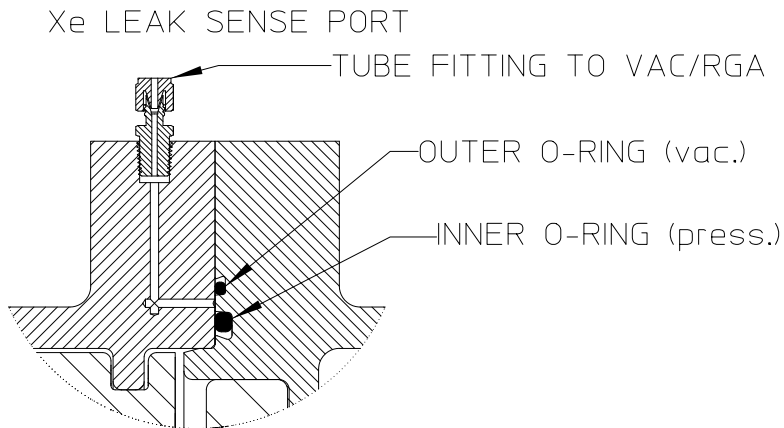




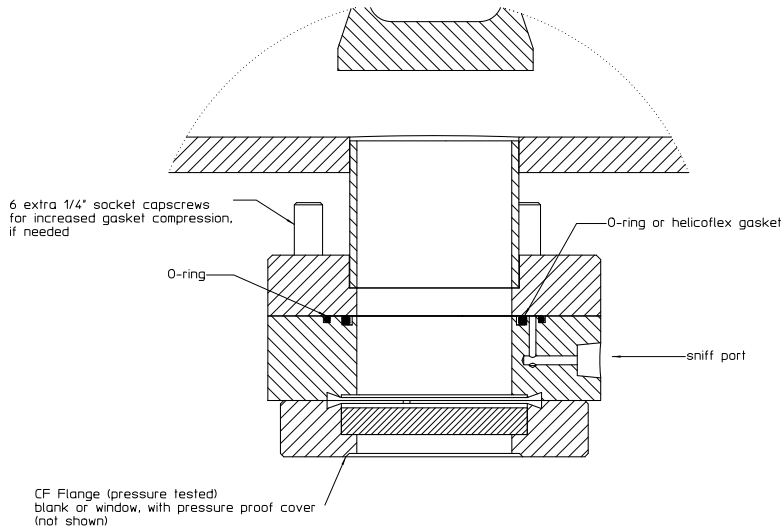
Parameter	qty	units
Maximum Operating Pressure (MOP)	15.0	bar (abs)
Maximum Allowable Working pressure (MAWP)	16.4	bar (abs)
Minimum Allowable Pressure (external)	1.5	bar (abs)
Material, stainless steel, alloy	316Ti	
Inner diameter	136	cm
Outer Diameter, Flanges	148	cm
Length, inside shielding	2.22	m
Vessel and head wall thickness	10	mm
Flange thickness, head to vessel (both)	4.1	cm
Bolt Diameter (Inconel 718), head to vessel flanges	16	mm
Number of Bolts, each head to vessel flange	132	
Mass, Vessel and both heads	1100	kg
Mass, Internal copper shielding	8500	kg
Total Weight	12000	kg

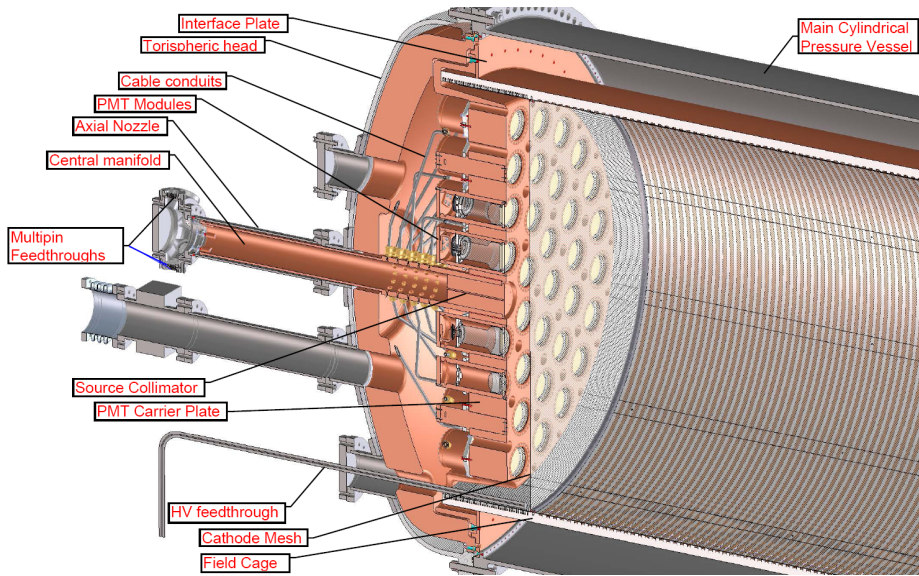


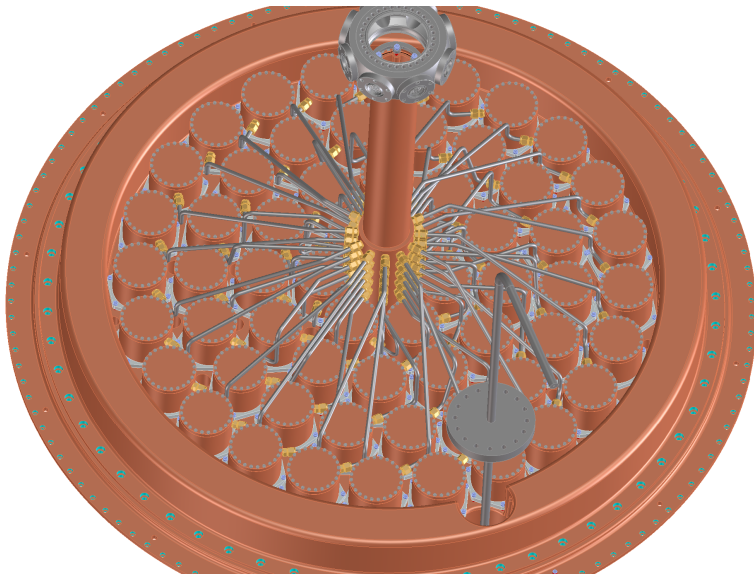
Double seal detail with leak sense port

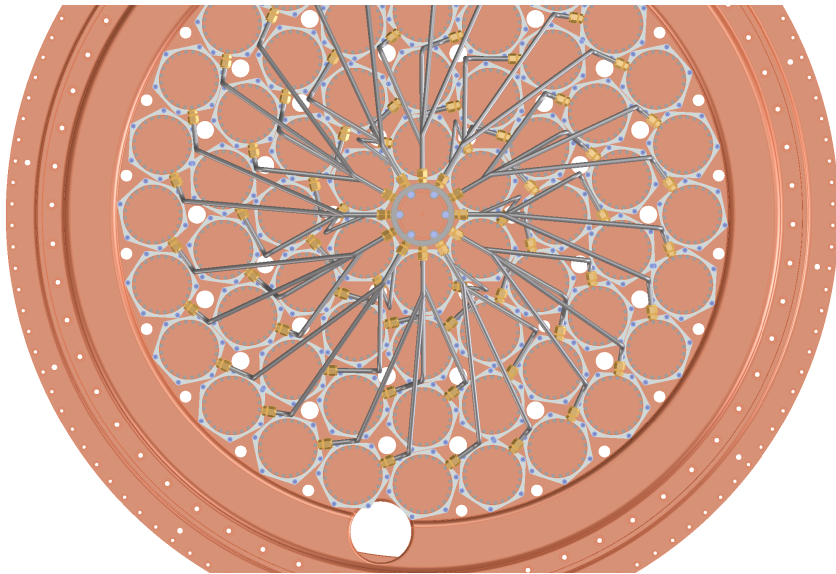


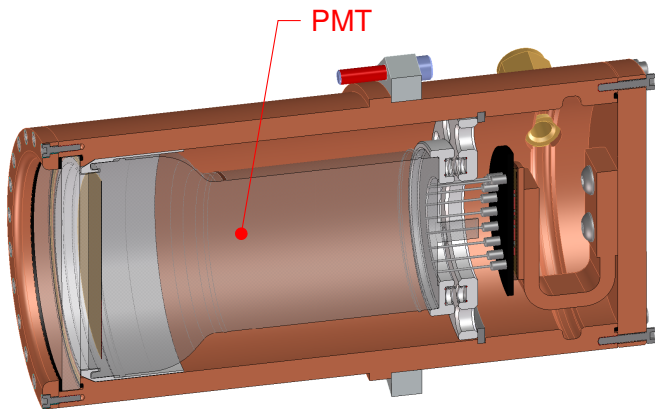
Interface flange detail

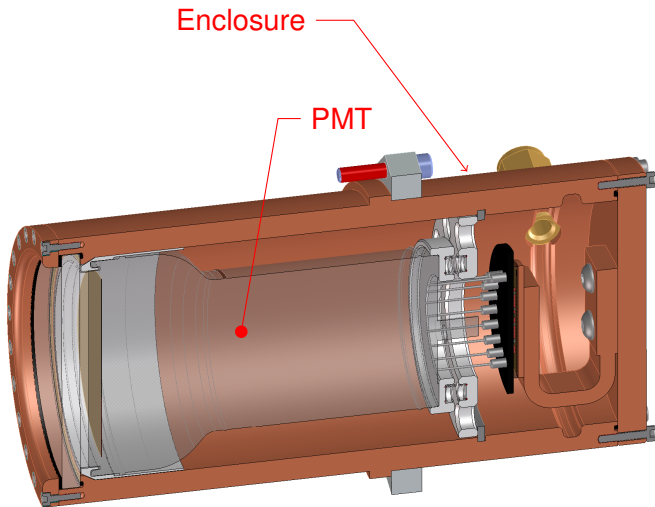


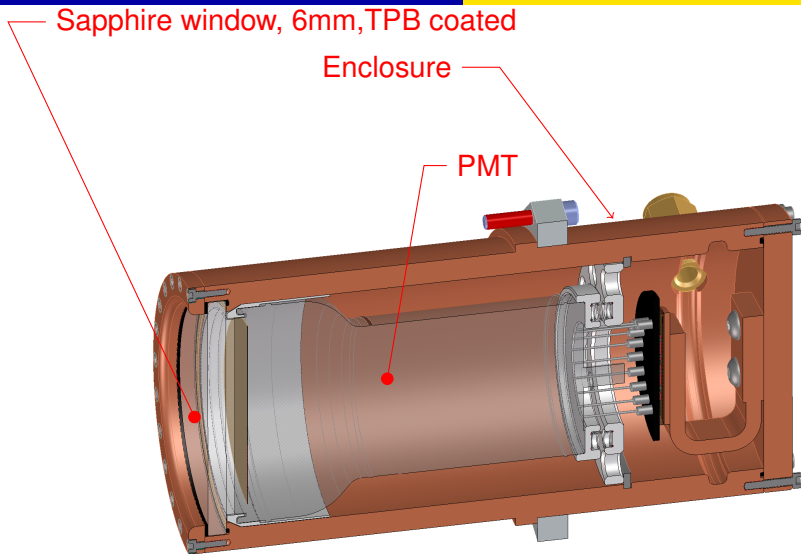


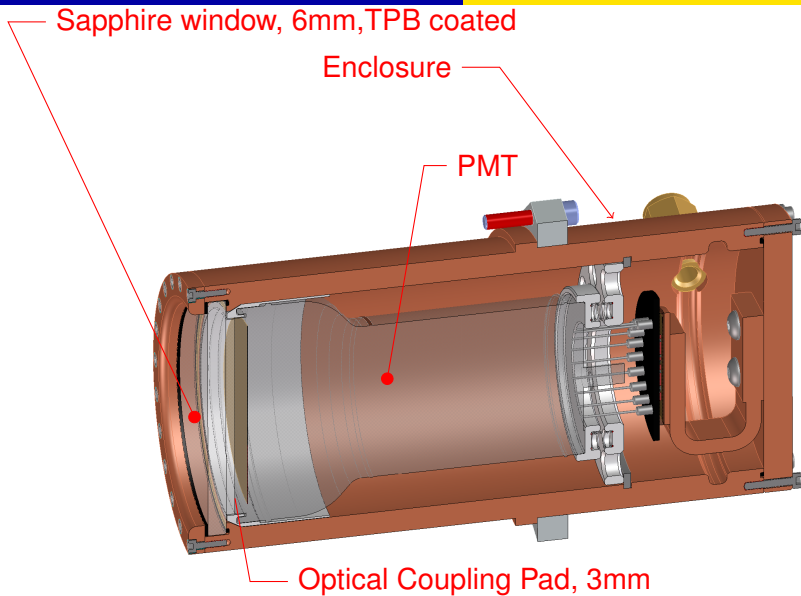


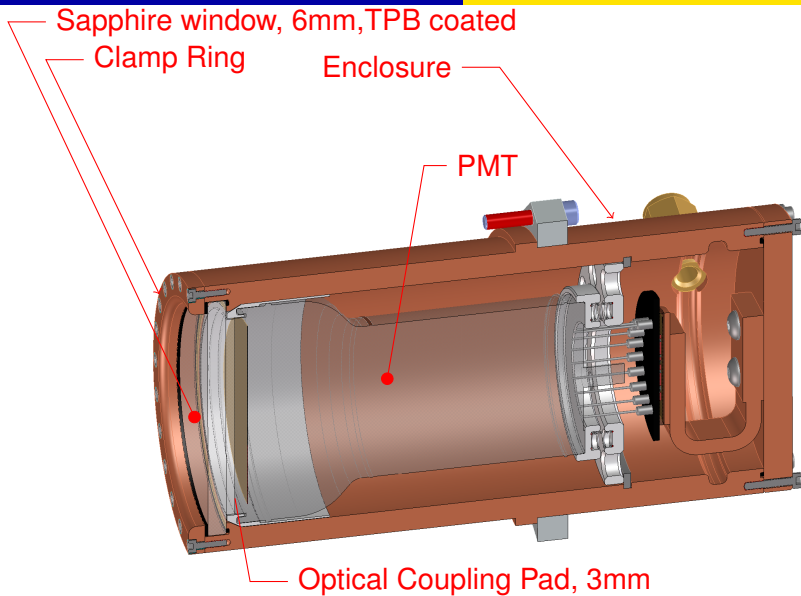


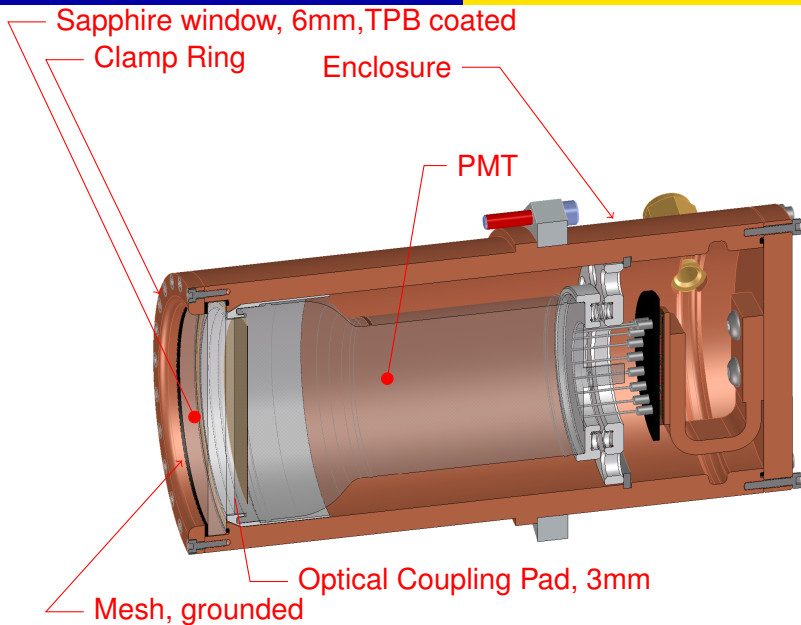


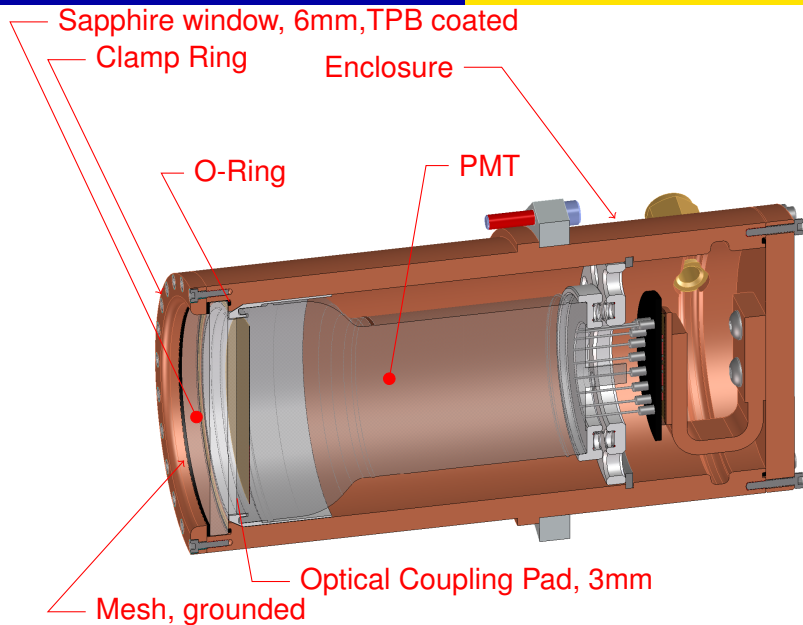


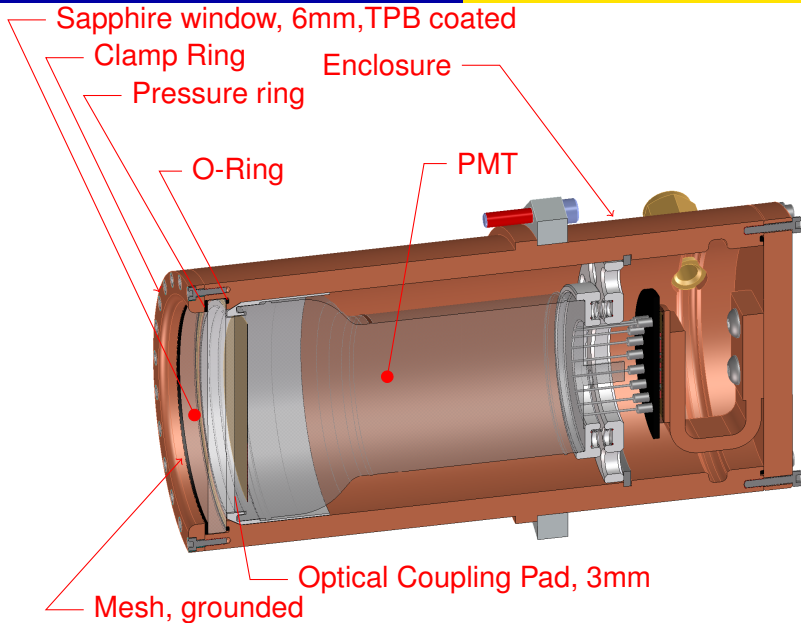


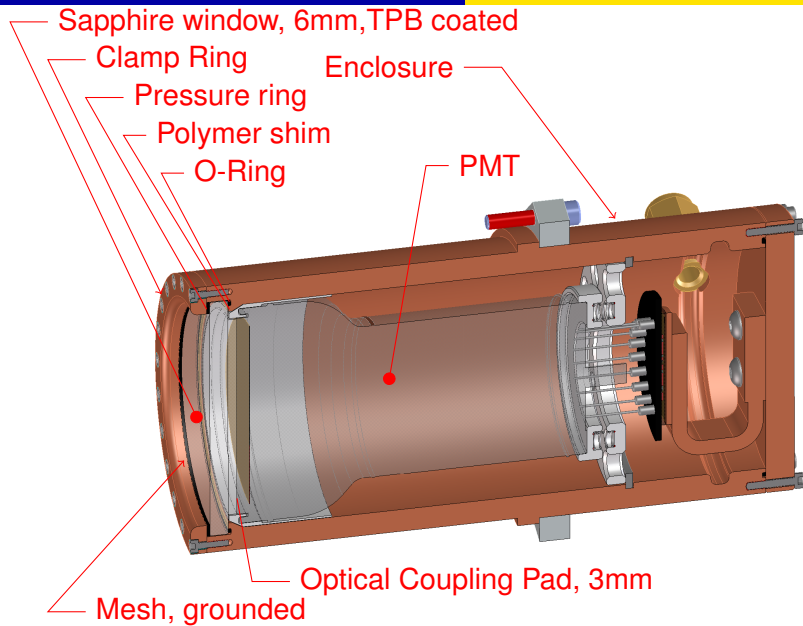


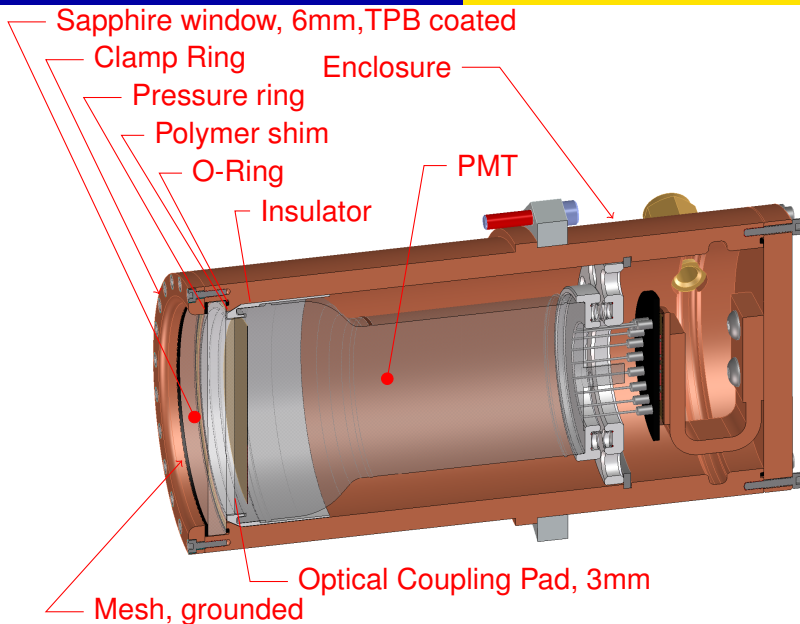


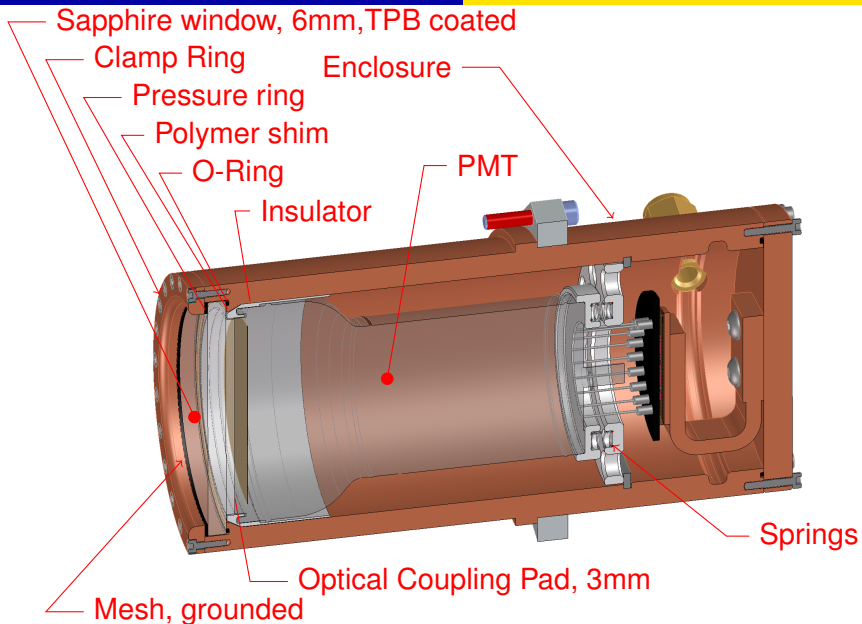


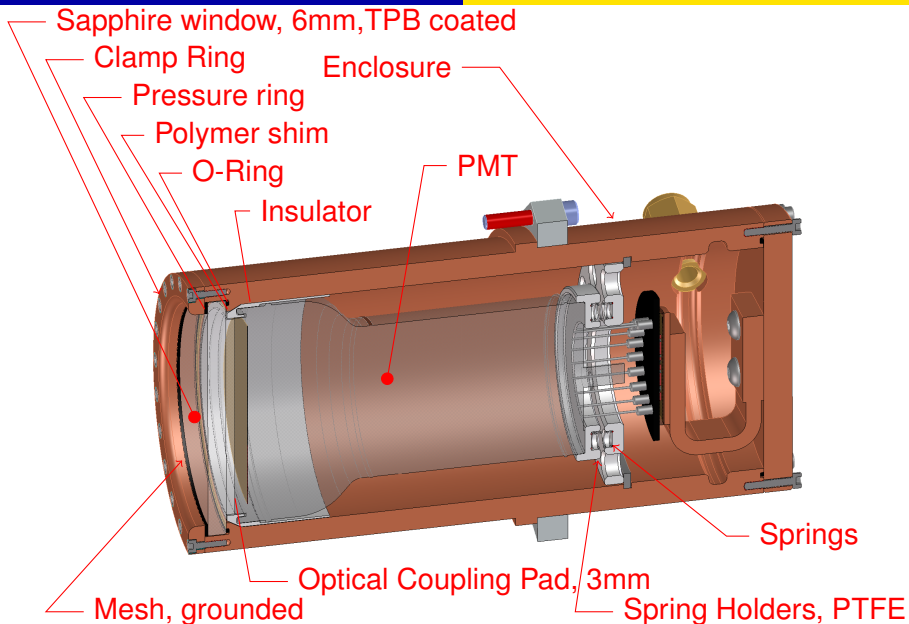


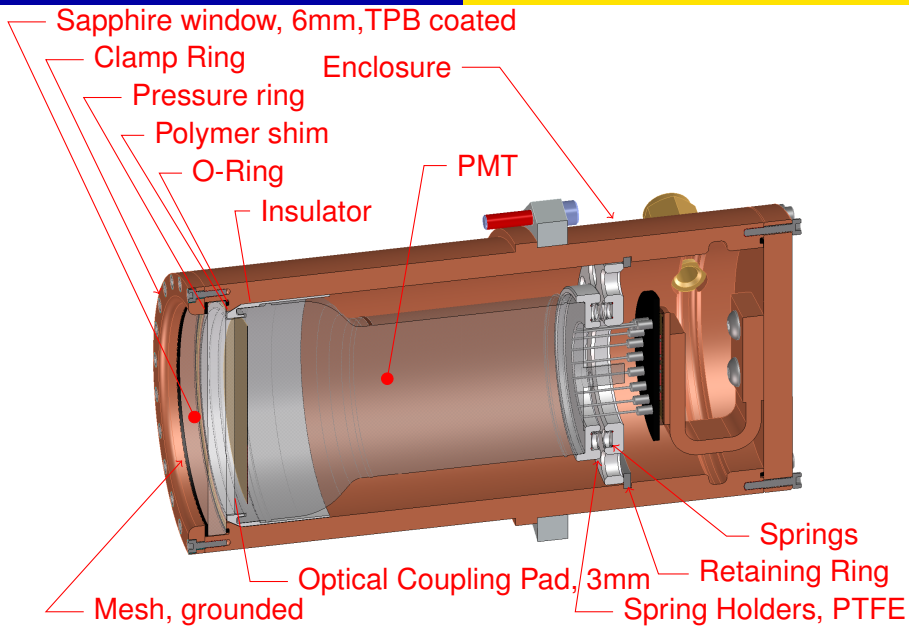


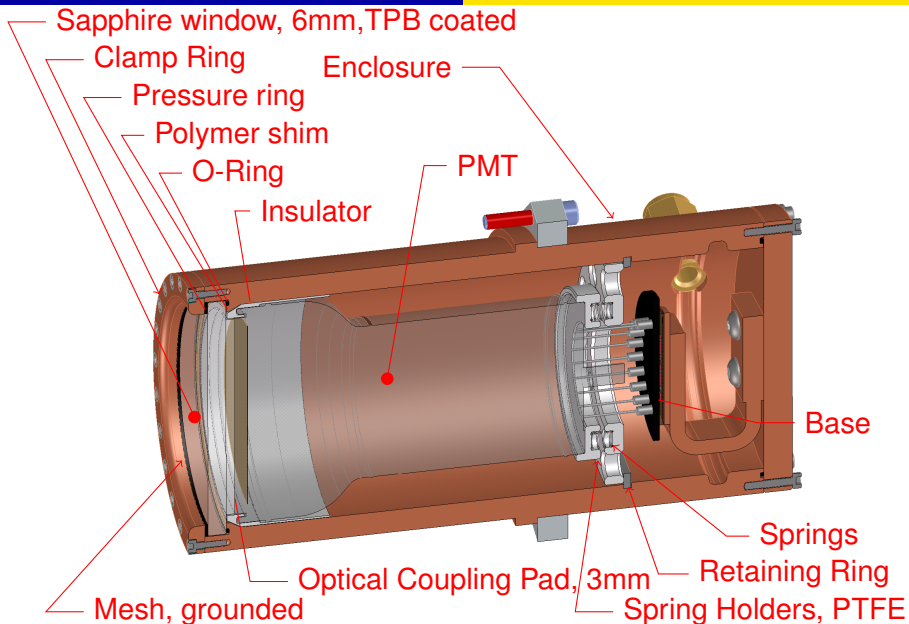


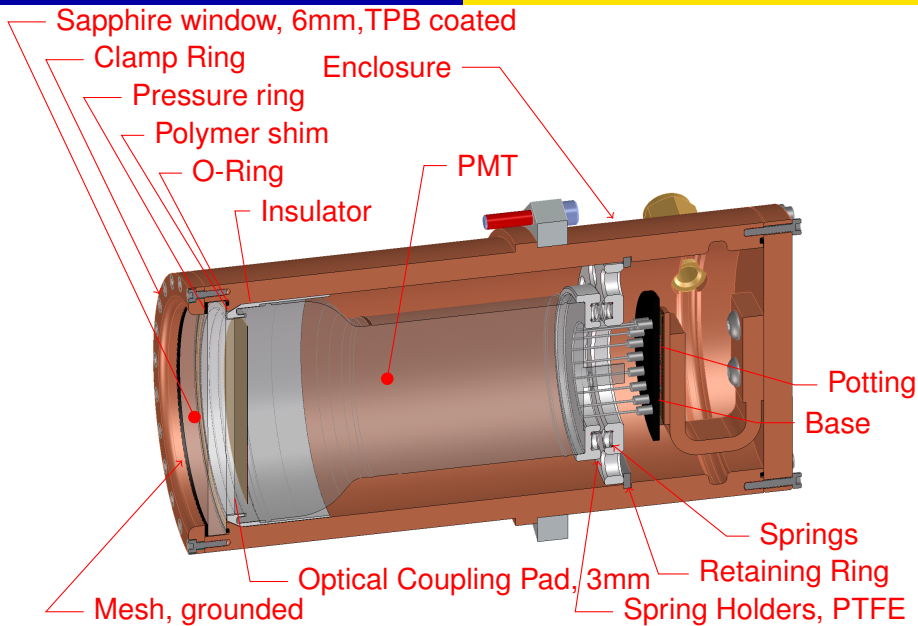


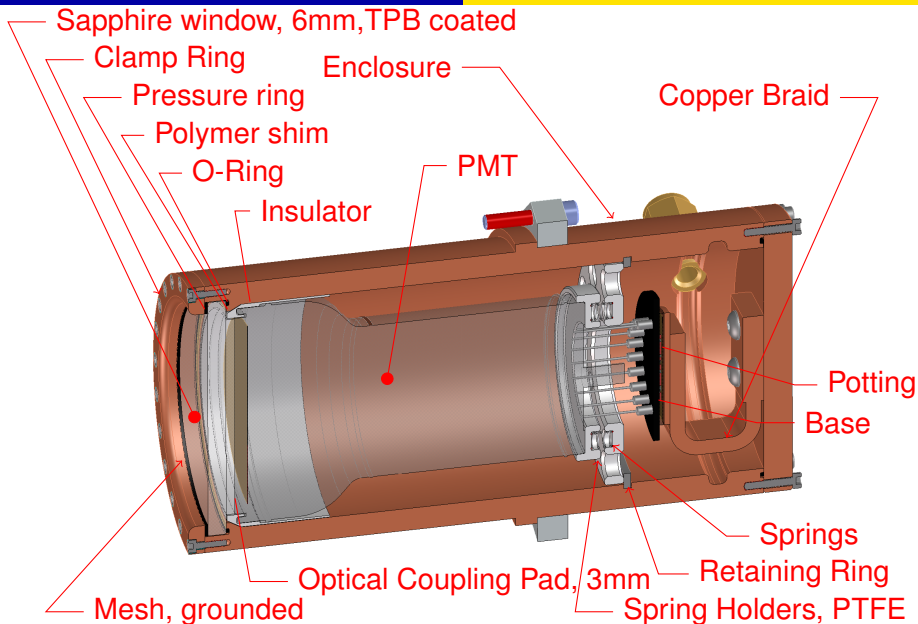


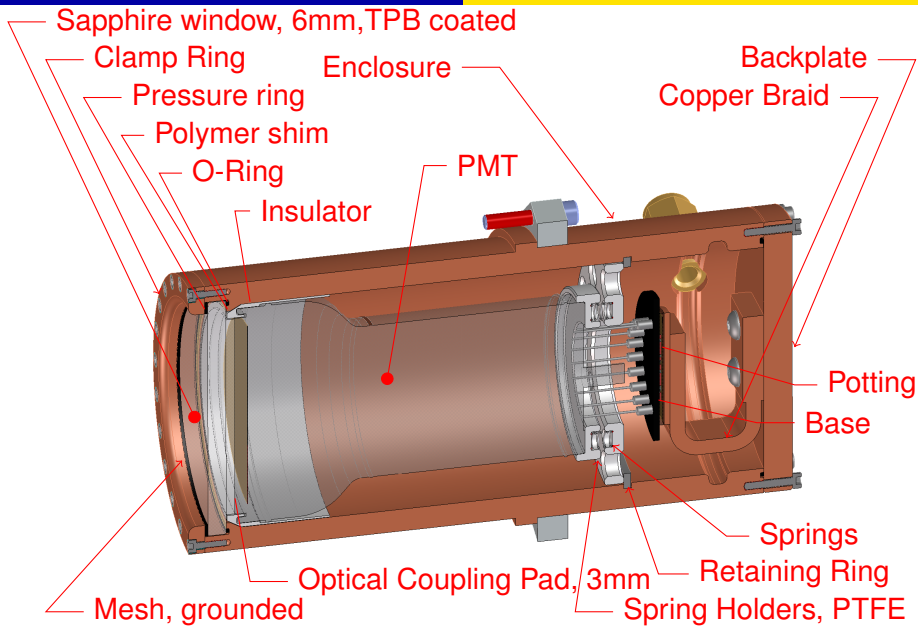


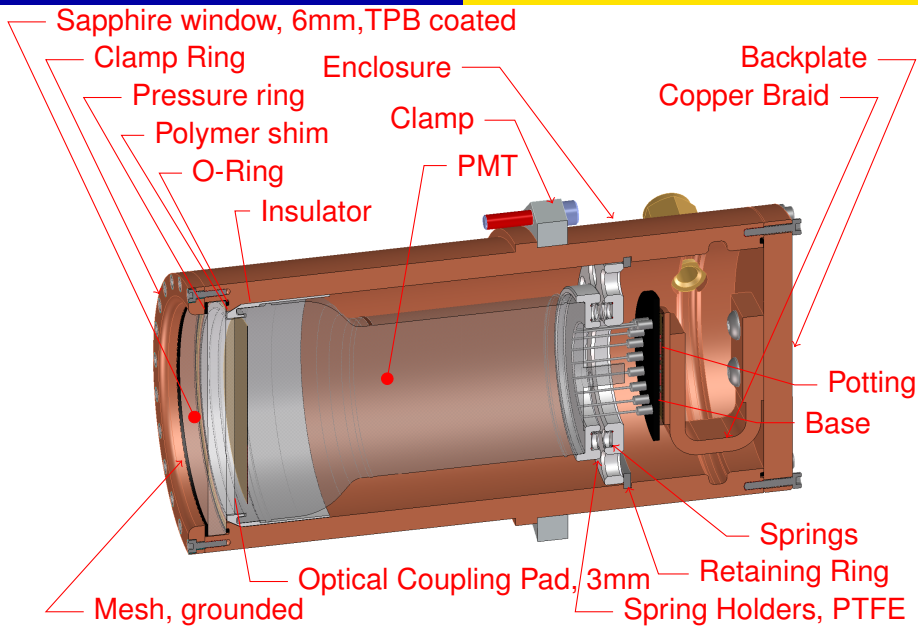


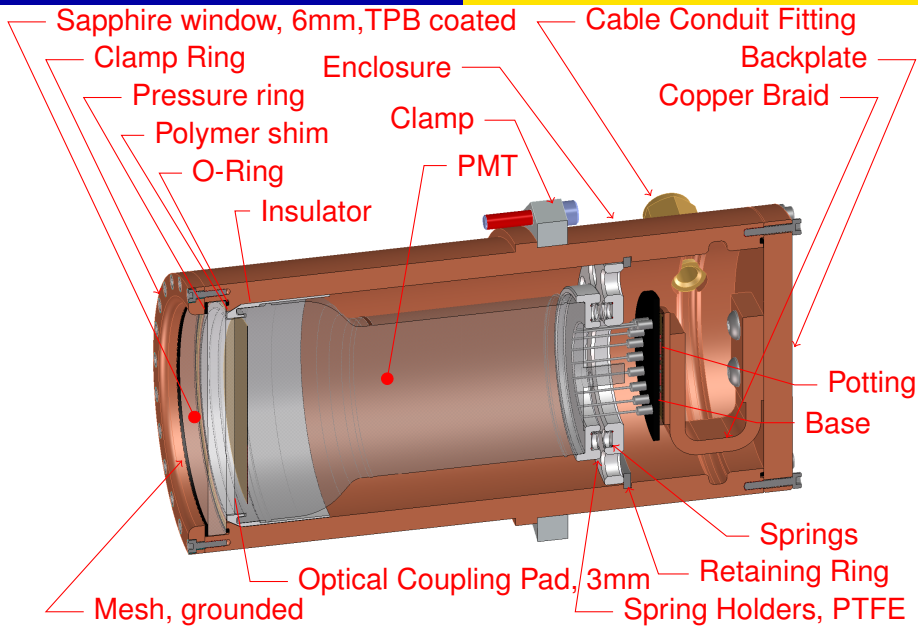


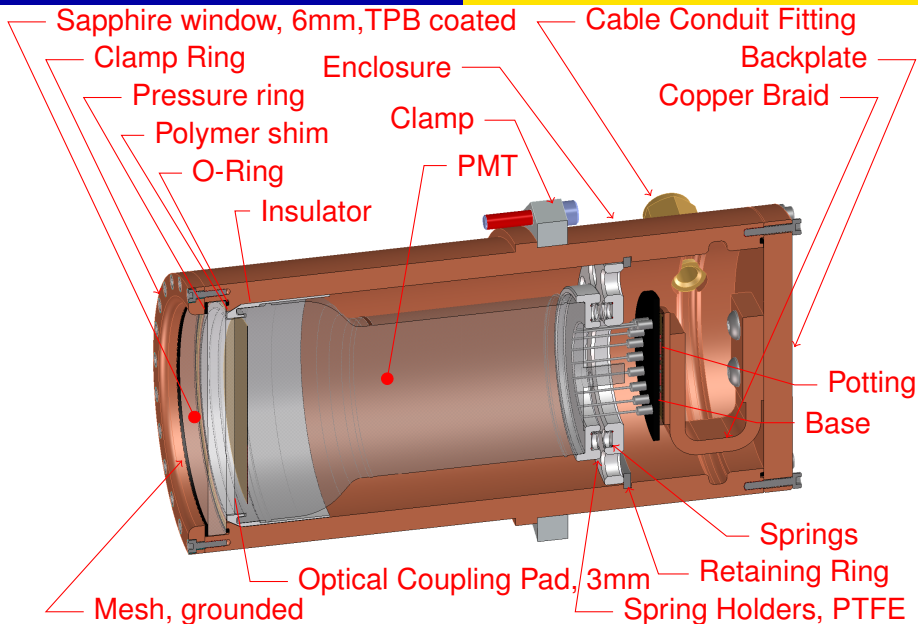






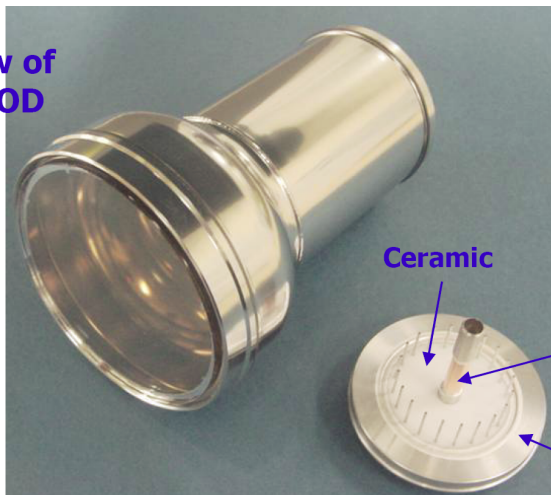






Hamamatsu R11410-10

Front view of R11410MOD



Ceramic

Cu Pipe

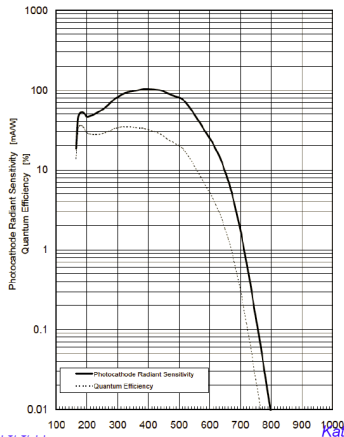
Kovar Metal

Typical quantum efficiencies, as measured, from [arisaka]

Spectral Response Characteristics

Tube Type: R11410-10
 Serial No.: 2K6346
 Date: Aug. 24, 2011
 Tested by: H.OISHI
 Note:

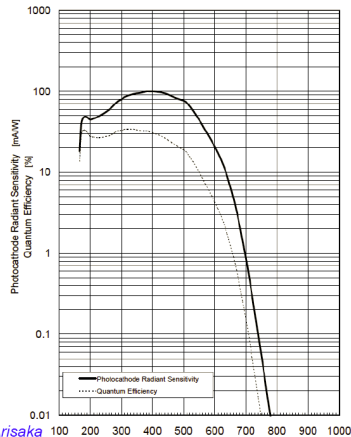
Max. Q.E.: 34.9 %
 Wavelength of max.: 320 nm



Spectral Response Characteristics

Tube Type: R11410-10
 Serial No.: KAD001
 Date: Aug. 24, 2011
 Tested by: H.OISHI
 Note:

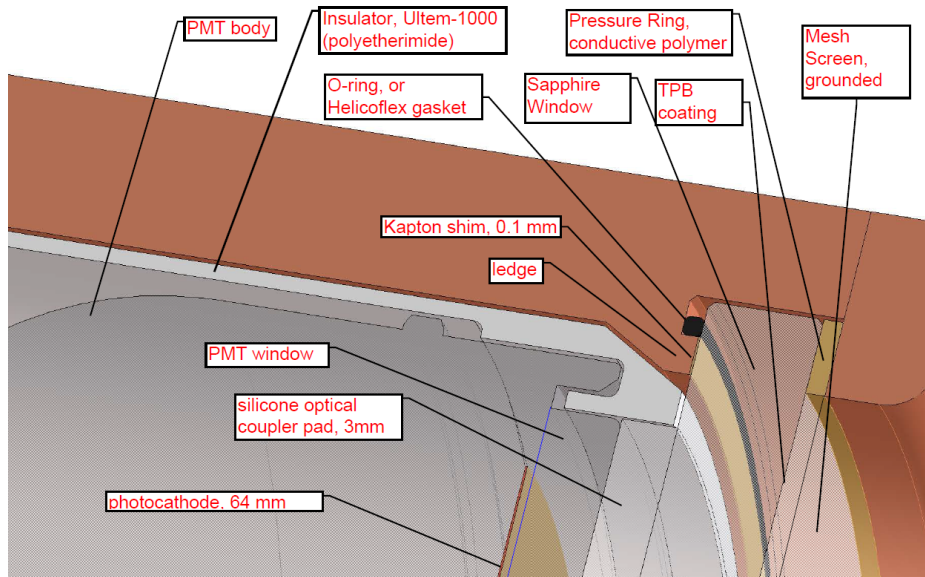
Max. Q.E.: 34.8 %
 Wavelength of max.: 320 nm



Katsushi Arisaka

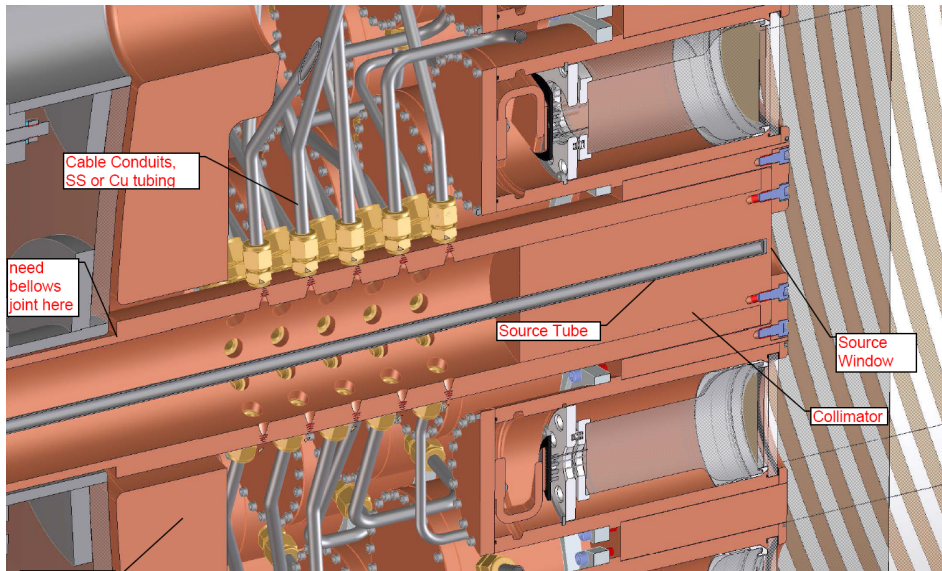
Window strength assurance

- Strength is a strong function of area and finish (as well as intrinsic strength)
- Weibull distribution: failure probability vs. stress-area function
- Sapphire and quartz have well characterized Weibull parameters (moduli and characteristic strength)
- Choose thickness, finish to give low failure probability (5% or less) at a TEST pressure
- Test pressure set to assure: if no failure under test then no failure under fatigue (cyclic or static)
- Pressure Test all windows

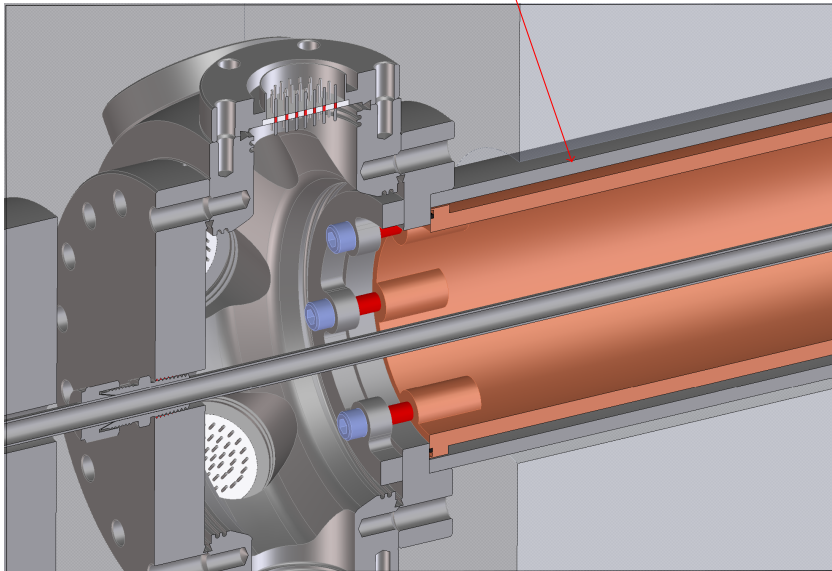


(Temperature Drop, Base to ambient @1750V, 3.5MOhm)

Section	deg. C
Potting Compound, 1mm (1W/(m*K))	2.38
Kapton MT insulation, .05mm	0.33
Cu braid, 259 kcmil x 7.5cm	1.34
Contact, into backplate	0.04
Contact, into enclosure	0.02
Enclosure to Clamp	0.17
Contact into Carrier Plate	0.02
Carrier plate to convolution	0.22
Convolution to Vessel flange	0.48
Vessel flange	1.32
Total Temp Drop	6.3

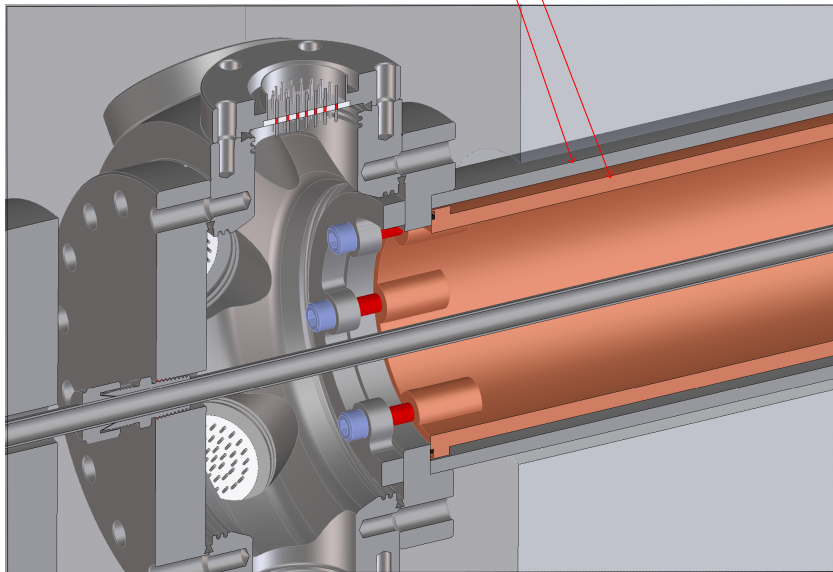


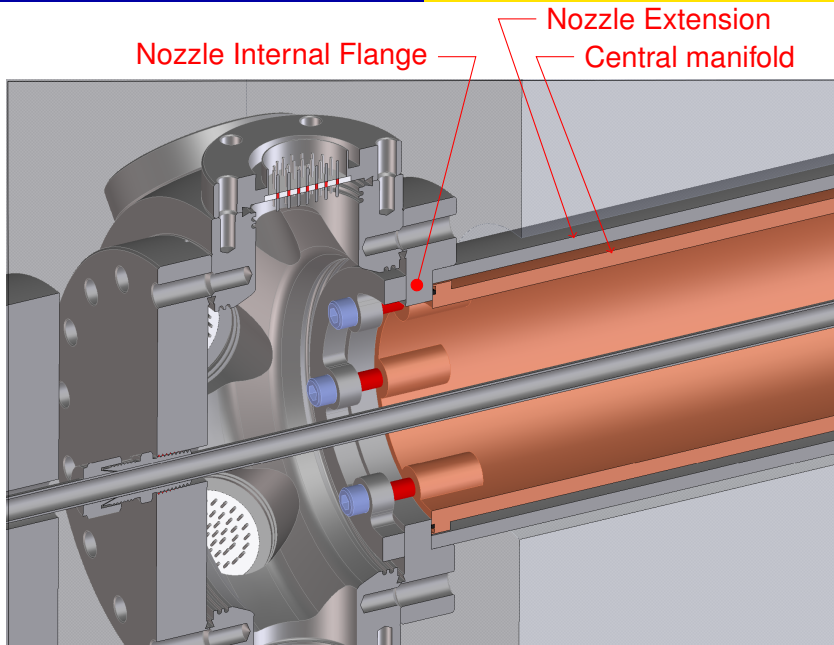
Nozzle Extension

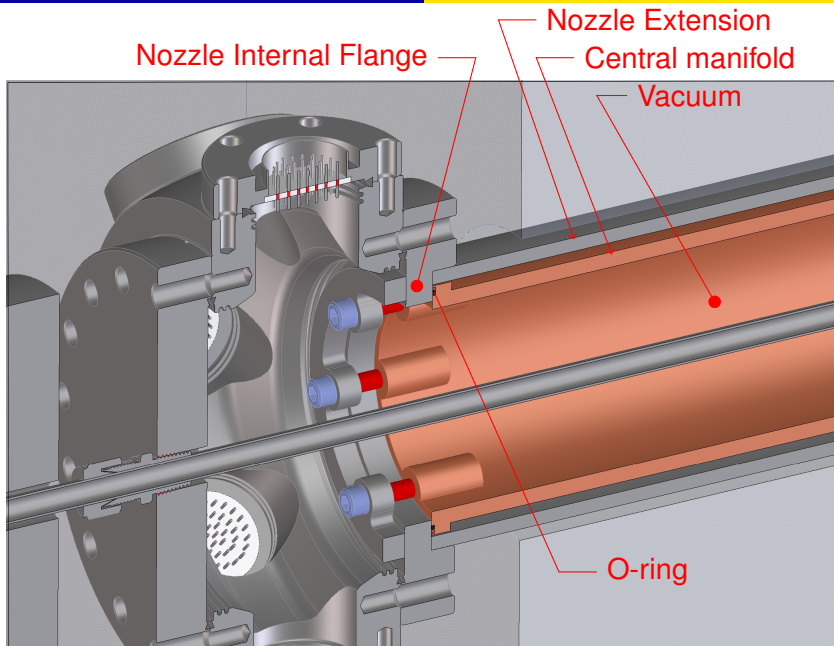


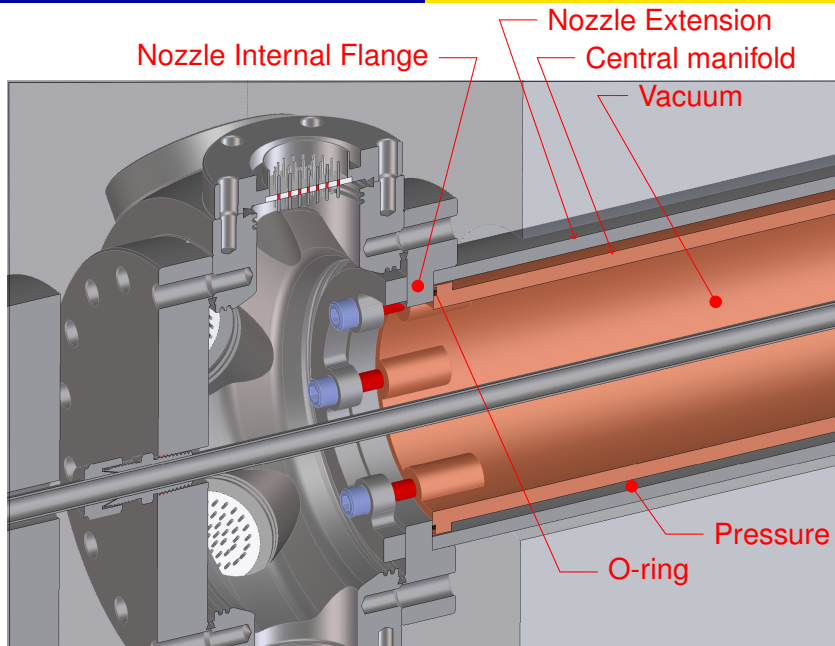
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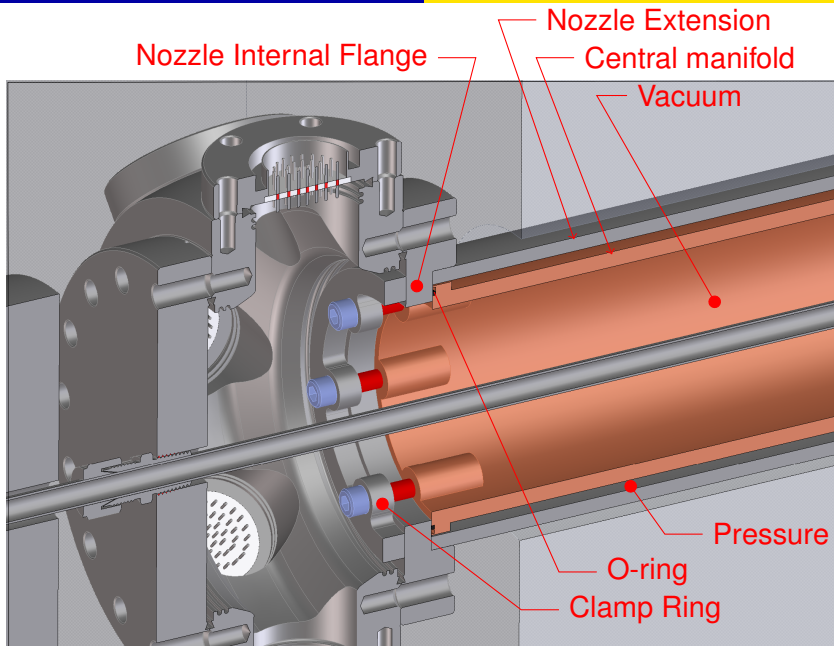
Central manifold

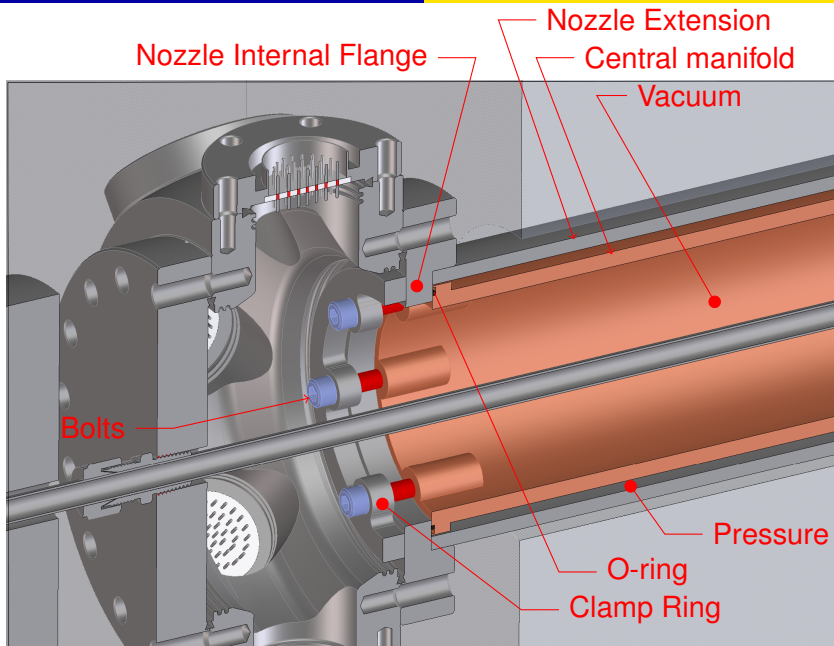


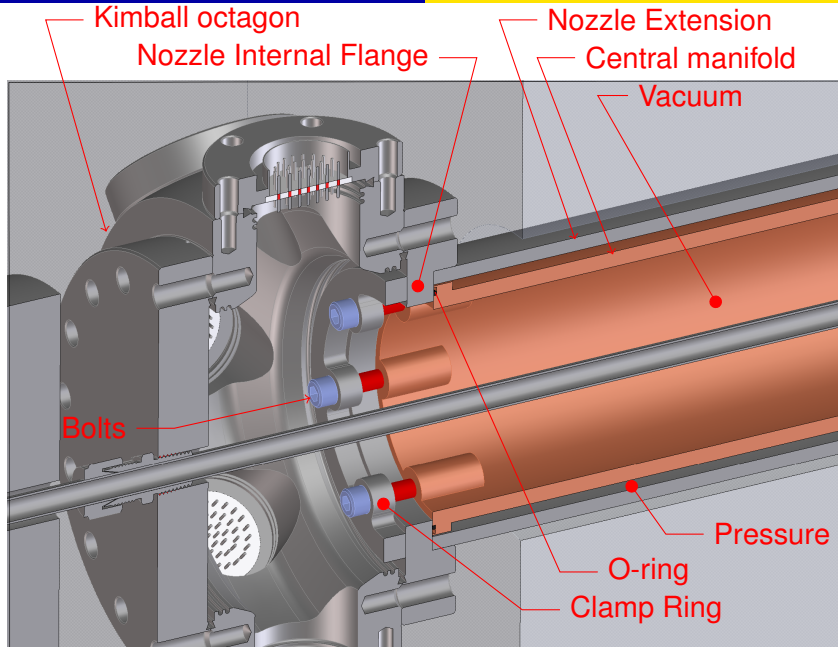


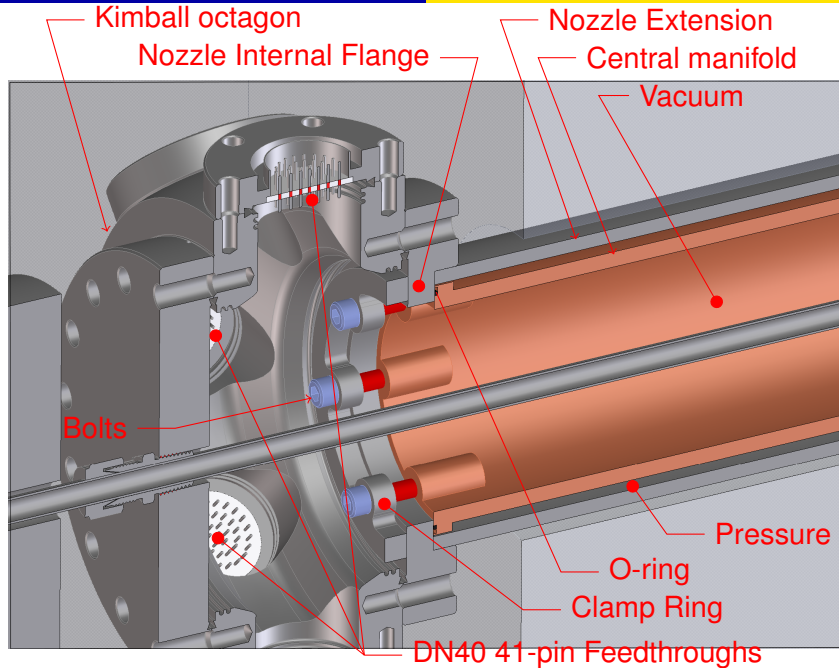


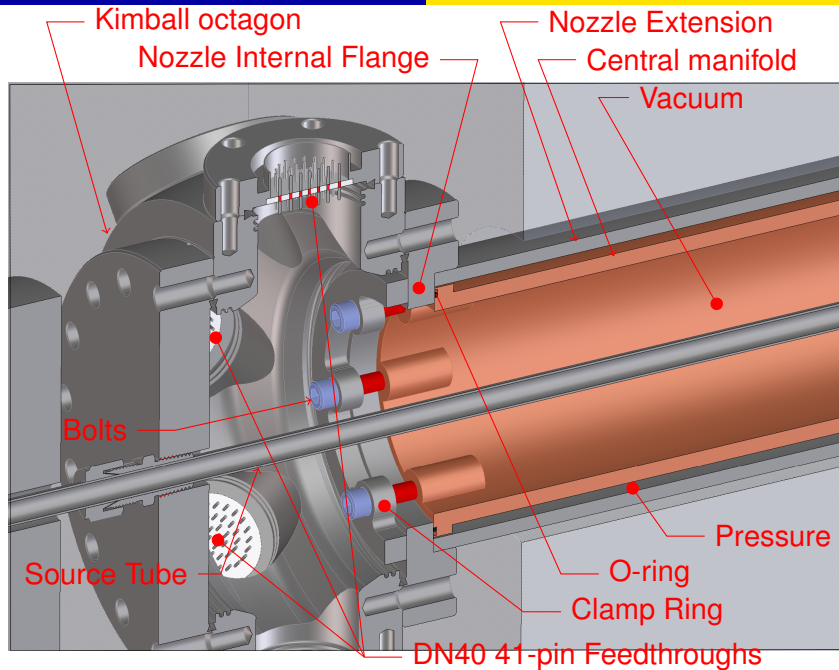


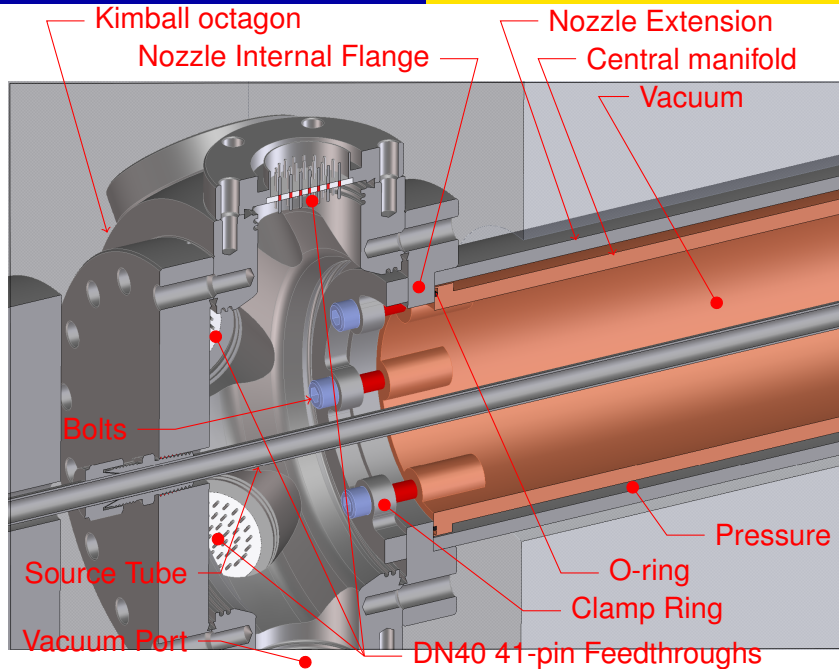


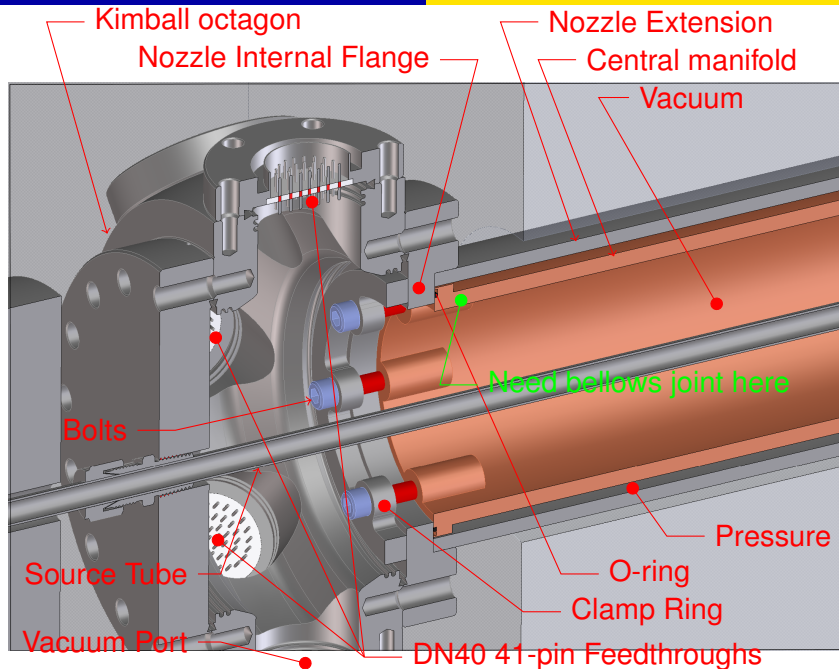


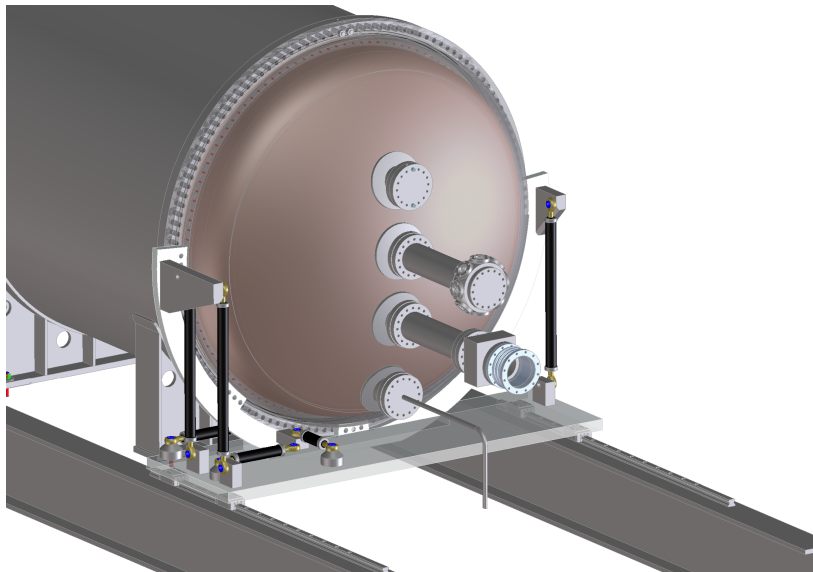












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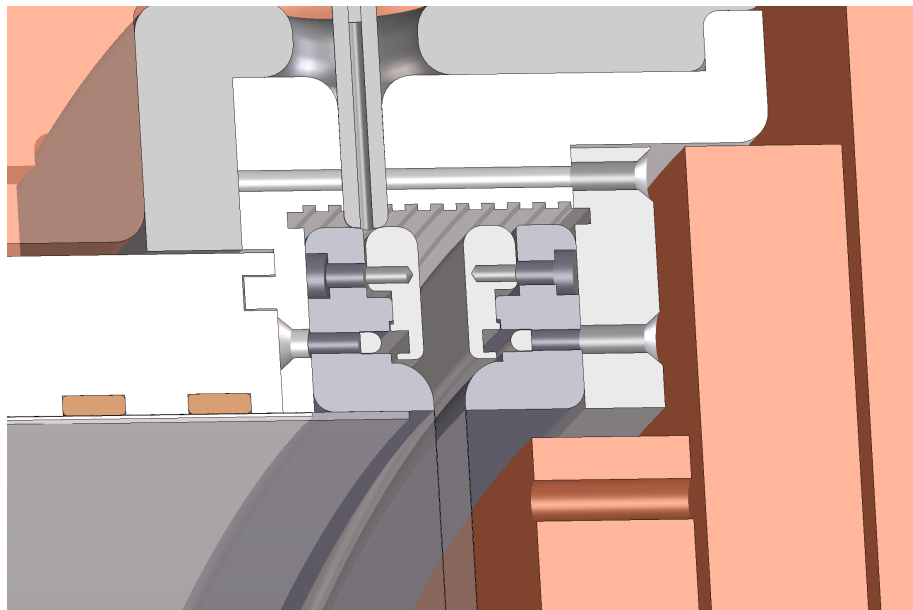
- Design by James White, Clement Sofka, TAMU
- 3cm polyethylene rotomolded and machined
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- "C-clamp" EL mesh connection avoids sparking or tracking

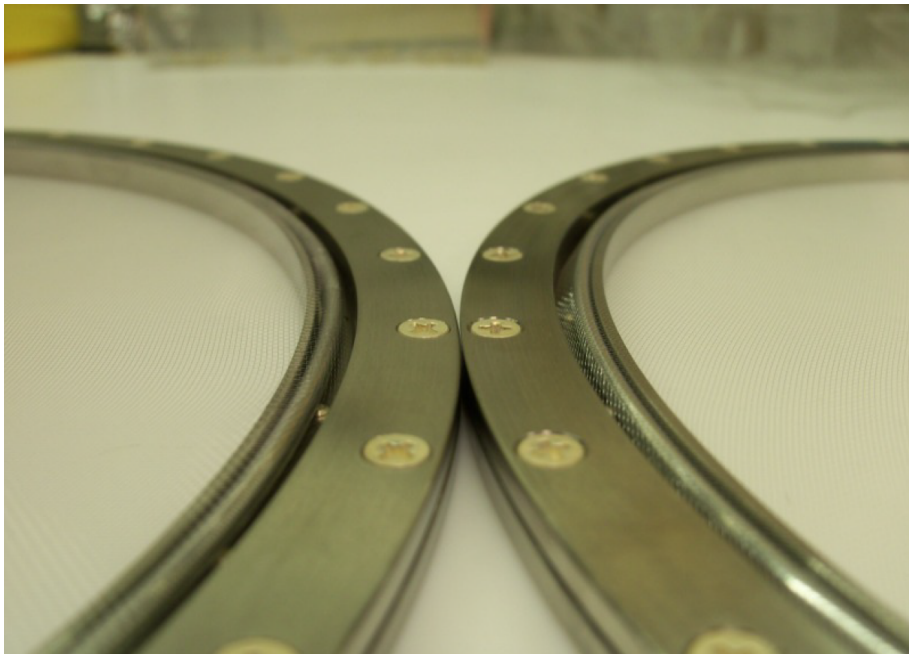
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- EL mesh of fine wire ($30\mu\text{m}$) and pitch (0.5mm), 88% transparent

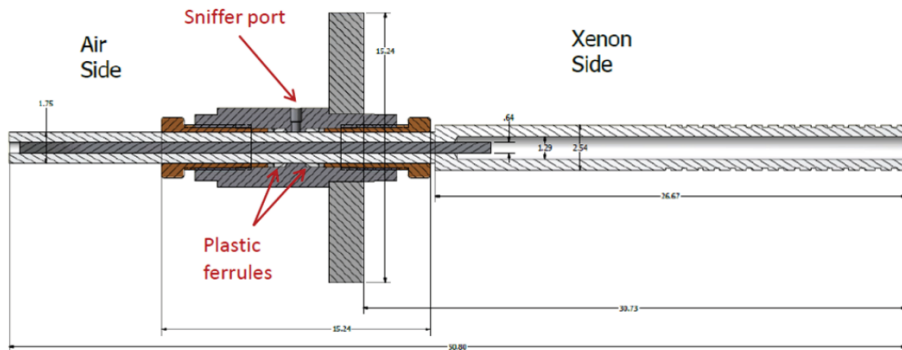
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- EL meshes and frame based on proven designs up to 50 cm dia.
- EL mesh of fine wire ($30\mu\text{m}$) and pitch (0.5mm), 88% transparent
- Coarse, stiff wire mesh on cathode for simplicity (88% transparent)

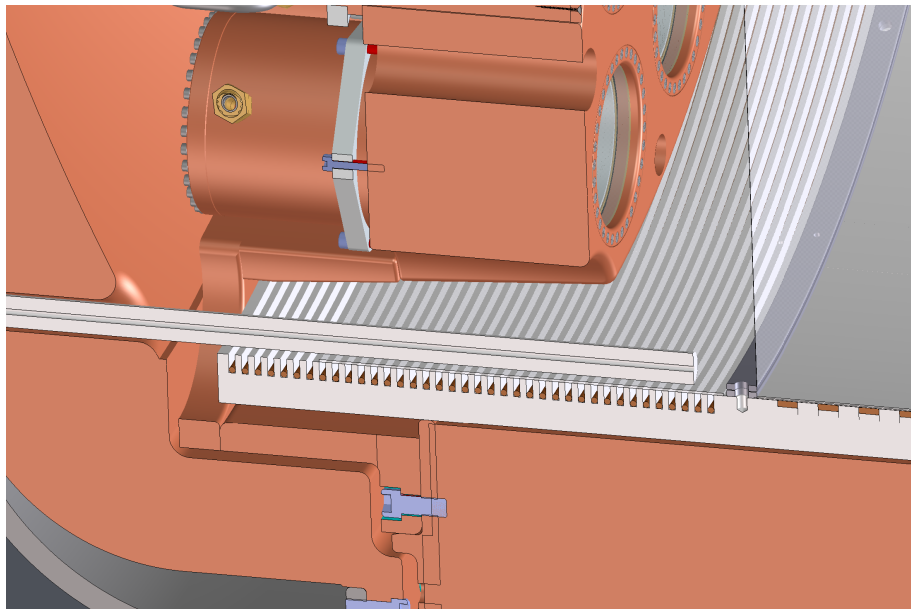
Drift field strength	0.3 kV cm^{-1}
EL field strength (E/p)	$3.0 \text{ kV cm}^{-1} \text{ bar}^{-1}$
Optical gain	$2500 \text{ photons/e}^{-}$
Drift length	130 cm
EL gap	0.5 cm
Cathode voltage	$-61.5 \text{ kV @15 bar (a)}$
Gate grid voltage	$-22.5 \text{ kV @15 bar (a)}$
Anode grid voltage	0

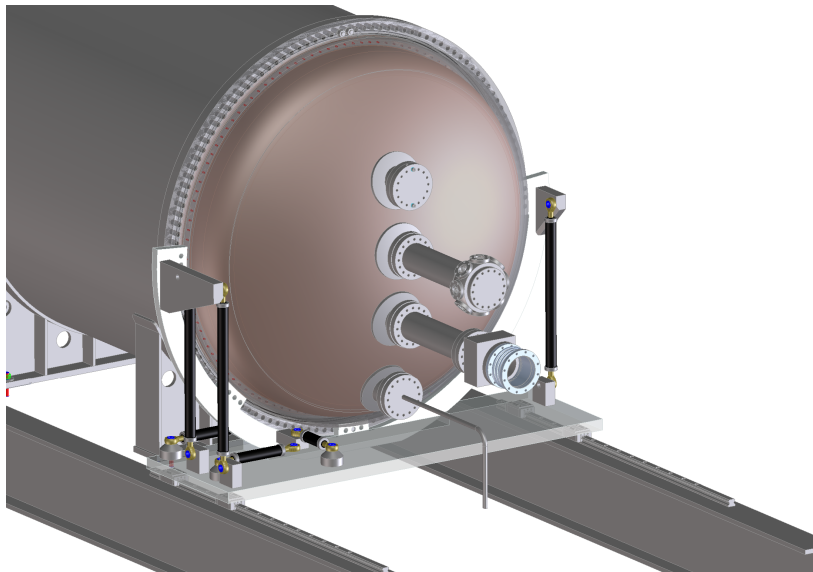




Tefzel insulator, will be graded on OD (contacts FC buffer grade down rings)







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- 111 Dice Boards (DBs) 80mm square pitch, 64 SiPMs/DB
- DB is 4 layer Cuflon multilam PCB, 80 pinout
- Xe flows around edges of each DB and behind them (no flow allowed elsewhere)
- DB carrier plate doubles as ICS shield (allows connectors inside vessel)
- ZIF connector (0.5mm pitch) on FPC cable attaches to DB pigtail, behind Cu shield

- 111 Dice Boards (DBs) 80mm square pitch, 64 SiPMs/DB
- DB is 4 layer Cuflon multilam PCB, 80 pinout
- Xe flows around edges of each DB and behind them (no flow allowed elsewhere)
- DB carrier plate doubles as ICS shield (allows connectors inside vessel)
- ZIF connector (0.5mm pitch) on FPC cable attaches to DB pigtail, behind Cu shield
- Cables (FPC) are stripline, 50Ω for reduced capacitance to ground

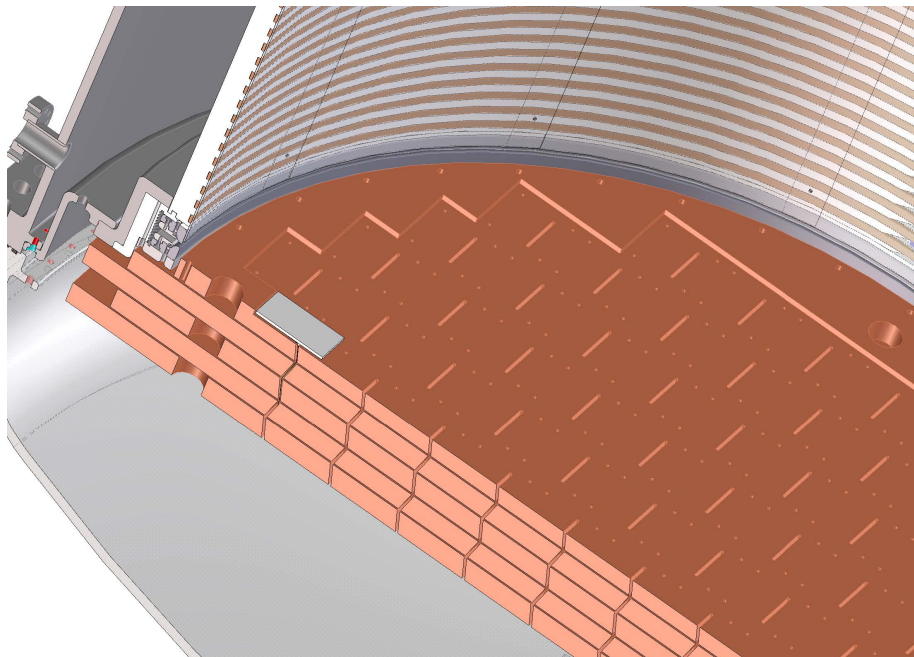
- 111 Dice Boards (DBs) 80mm square pitch, 64 SiPMs/DB
- DB is 4 layer Cuflon multilam PCB, 80 pinout
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- Cables bundled into 3 sets, rest on shelves cantilevered from shield

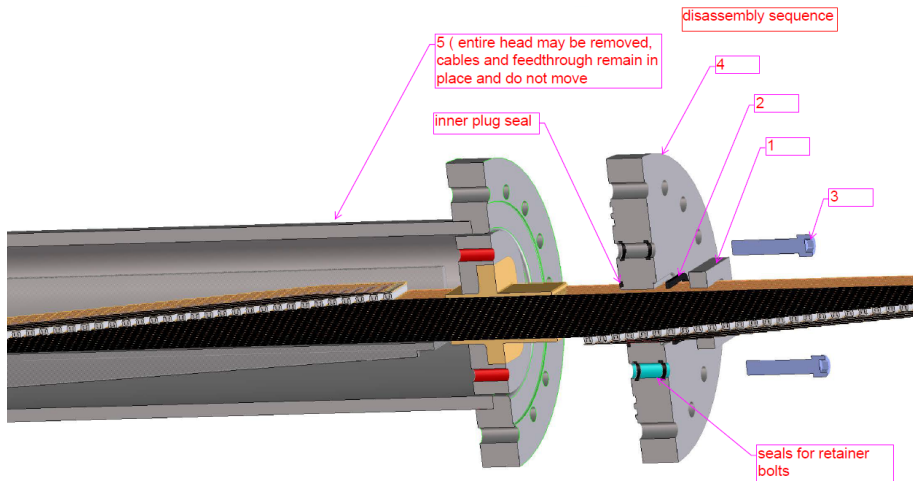
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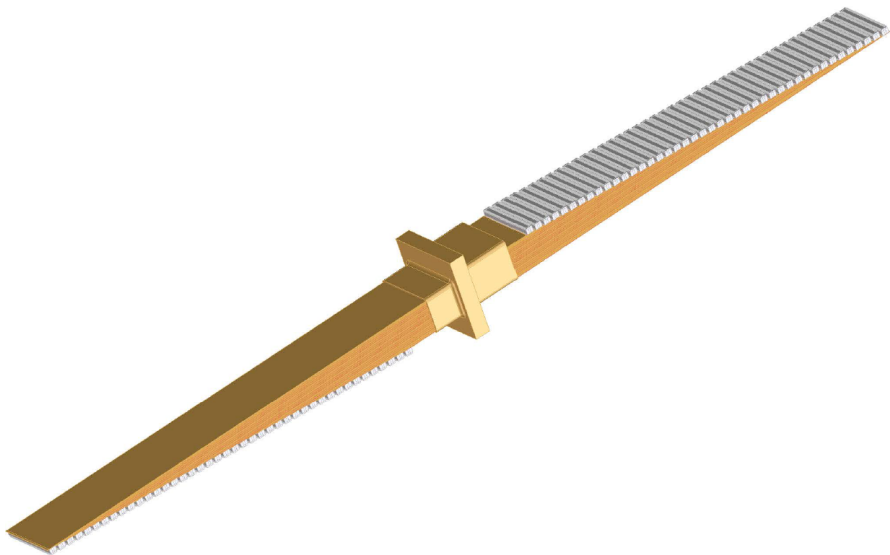
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LBNL Feedthrough Stripline FPC Design Proposal

